

DATA SHEET

SA1920

Dual-band RF front-end

Product specification
Supersedes data of 1998 Apr 07
IC17 Data Handbook

1999 Mar 02

Dual-band RF front-end

SA1920

DESCRIPTION

The SA1920 is an integrated dual-band RF front-end that operates at both cellular (AMPS, GSM and TDMA) and PCS/DCS (TDMA and GSM) frequencies, and is designed in a 13 GHz f_T BiCMOS process—QUBiC1. The low-band is a combined low-noise amplifier (LNA) and mixer. The LNA has a 1.7 dB noise figure at 881 MHz with 17.5 dB of gain and an IIP3 of -5 dBm. The wide-dynamic range mixer has a 10 dB noise figure at 881 MHz with 9.5 dB of gain and an IIP3 of +5 dBm.

The high-band contains a receiver front-end, doubler and a high frequency transmit mixer intended for closed loop transmitters. One advantage of the high-band architecture is an image-rejection mixer with over 30 dB of image rejection; thus, eliminating external filter cost while saving board space. The system noise figure is 4.2 dB at 1960 MHz with a power gain of 23.5 dB and an IIP3 of -12.5 dB.

FEATURES

- Low current consumption
- Outstanding low- and high-band noise figure
- Excellent gain stability versus temperature and supply
- Image reject high-band mixer with over 30 dB of rejection
- Increased low-band LNA gain compression during analog transmission
- LO input and output buffers
- Frequency doubler
- On chip logic for network selection and power down
- Very small outline package

APPLICATIONS

- 800 to 1000 MHz analog and digital receivers
- 1800 to 2000 MHz digital receivers
- Portable radios
- Digital mobile communications equipment

PIN CONFIGURATION

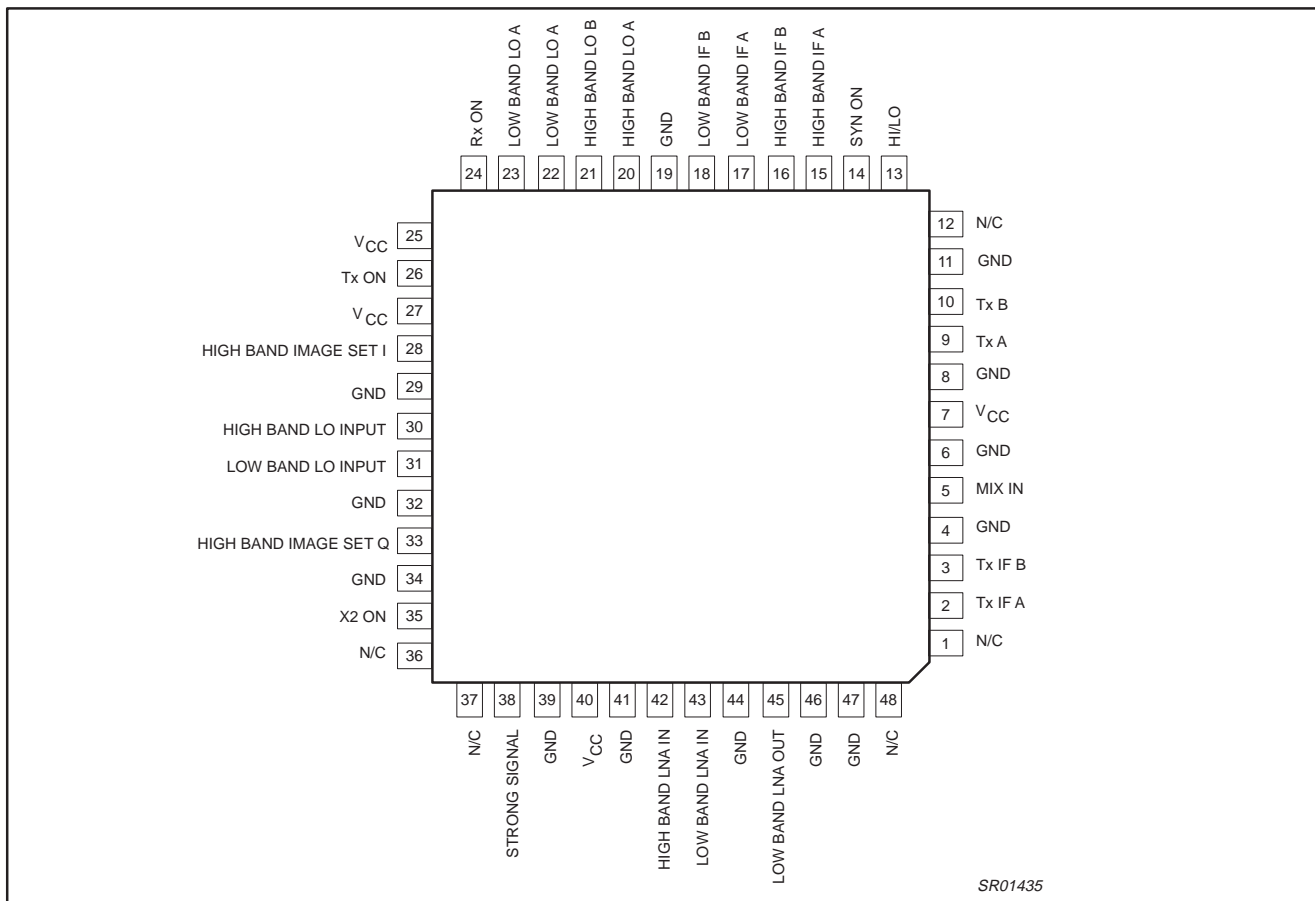


Figure 1. Pin Configuration

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | |
|-------------|---------|--|----------|
| | NAME | DESCRIPTION | VERSION |
| SA1920 | LQFP48 | Plastic low profile quad flat package; 48 leads; body 7x7x1.4 mm | SOT313-2 |

Dual-band RF front-end

SA1920

PIN DESCRIPTIONS

| PIN NO. | PIN NAME | DESCRIPTION |
|---------|-----------------------|-----------------------------|
| 1 | N/C | No Connection |
| 2 | Tx IF A | Transmit IF A |
| 3 | Tx IF B | Transmit IF B |
| 4 | GND | Ground |
| 5 | MIX IN | Low Band Mixer Input |
| 6 | GND | Ground |
| 7 | V _{CC} | V _{CC} |
| 8 | GND | Ground |
| 9 | Tx A | Transmit Signal A |
| 10 | Tx B | Transmit Signal B |
| 11 | GND | Ground |
| 12 | N/C | No Connection |
| 13 | HI/LO | High Band/Low Band Control |
| 14 | SYN ON | LO Buffer Power Control |
| 15 | HIGH BAND IF A | High Band IF A |
| 16 | HIGH BAND IF B | High Band IF B |
| 17 | LOW BAND IF A | Low Band IF A |
| 18 | LOW BAND IF B | Low Band IF B |
| 19 | GND | Ground |
| 20 | HIGH BAND LO A | High Band LO Output |
| 21 | HIGH BAND LO B | High Band LO Output |
| 22 | LOW BAND LO A | Low Band LO Output |
| 23 | LOW BAND LO B | Low Band LO Output |
| 24 | Rx ON | LNA/Mixer Power Control |
| 25 | V _{CC} | V _{CC} |
| 26 | Tx ON | Tx Mixer/Driver Power |
| 27 | V _{CC} | V _{CC} |
| 28 | HIGH BAND IMAGE SET I | High Band Image Set I |
| 29 | GND | Ground |
| 30 | HIGH BAND LO INPUT | High Band LO Connection |
| 31 | LOW BAND LO INPUT | Low Band LO Connection |
| 32 | GND | Ground |
| 33 | HIGH BAND IMAGE SET Q | High Band Image Set Q |
| 34 | GND | Ground |
| 35 | X2 ON | Freq. Doubler Power Control |
| 36 | N/C | No Connection |
| 37 | N/C | No Connection |
| 38 | STRONG SIGNAL | Strong Signal Detection |
| 39 | GND | Ground |
| 40 | V _{CC} | V _{CC} |
| 41 | GND | Ground |
| 42 | HIGH BAND LNA IN | High Band LNA Input |
| 43 | LOW BAND LNA IN | Low Band LNA Input |
| 44 | GND | Ground |
| 45 | LOW BAND LNA OUT | Low Band LNA Output |
| 46 | GND | Ground |
| 47 | GND | Ground |
| 48 | N/C | No Connection |

Dual-band RF front-end

SA1920

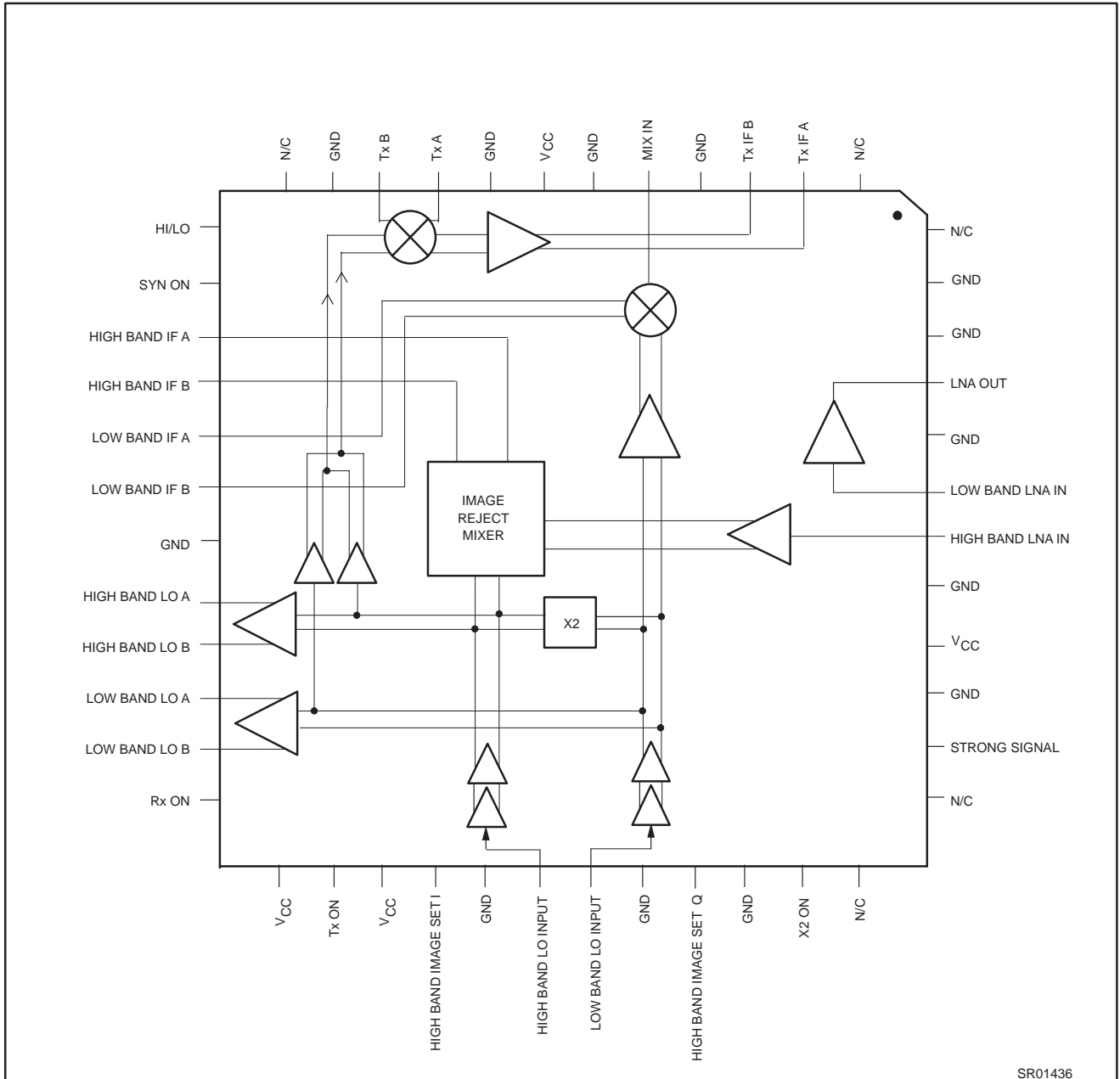


Figure 2. Block Diagram

Dual-band RF front-end

SA1920

Table 1. POWER DOWN CONTROL

For **Applications Not Using a Frequency Doubler**, each state is defined as follows:

| Control State (Hi/Lo, Syn On, Rx On, Tx On, Strong Signal, X2 ON) | | DOUBLER | LO BUFFER | | LNA | | MIXER | | Tx MIXER DRIVER | |
|--|---------------------------------|---------|-----------|----------|-----------|-----------------|-----------|----------|-----------------|----------|
| | | | High Band | Low Band | High Band | Low Band | High Band | Low Band | High Band | Low Band |
| x000xx | Sleep | Off | Off | Off | Off | Off | Off | Off | Off | Off |
| 010000 | Low-Band LO Buffer on | Off | Off | On | Off | Off | Off | Off | Off | Off |
| 011000 | Low-Band Receive Normal | Off | Off | On | Off | On | Off | On | Off | Off |
| 011010 | Low-Band receive Strong Signal | Off | Off | On | Off | Off | Off | On | Off | Off |
| 011100 | Low-Band Transmit (Analog only) | Off | Off | On | Off | On High Bias | Off | On | Off | On |
| 010100 | N/A | Off | Off | On | Off | Off | Off | Off | Off | On |
| 110000 | High-Band LO Buffer On | Off | On | Off | Off | Off | Off | Off | Off | Off |
| 111000 | High-Band Receive Normal | Off | On | Off | On | Off | On | Off | Off | Off |
| 111010 | High-Band Receive Strong Signal | Off | On | Off | Off | Off | On | Off | Off | Off |
| 110100 | N/A | Off | On | Off | Off | Off | Off | Off | On | Off |

For **Applications Using a Frequency Doubler**, each state is defined as follows:

| Control State (Hi/Lo, Syn On, Rx On, Tx On, Strong Signal, X2 ON) | | DOUBLER | LO BUFFER | | LNA | | MIXER | | Tx MIXER DRIVER | |
|--|---------------------------------|---------|-----------|----------|-----------|-----------------|-----------|----------|-----------------|----------|
| | | | High Band | Low Band | High Band | Low Band | High Band | Low Band | High Band | Low Band |
| x000xx | Sleep | Off | Off | Off | Off | Off | Off | Off | Off | Off |
| 010000 | Transmit (Low and High Band) | Off | Off | On | Off | Off | Off | Off | Off | Off |
| 011000 | Low-Band Receive Normal | Off | Off | On | Off | On | Off | On | Off | Off |
| 011010 | Low-Band Receive Strong Signal | Off | Off | On | Off | Off | Off | On | Off | Off |
| 011110 | Low-Band Transmit (Analog only) | Off | Off | On | Off | On High Bias | Off | On | Off | Off |
| 010100 | Low-Band Transmit (GSM) | Off | Off | On | Off | Off | Off | Off | Off | On |
| 010001 | Transmit (Low and High Band) | On | Off | On | Off | Off | Off | Off | Off | Off |
| 011001 | Low-Band Receive Normal | On | Off | On | Off | On | Off | On | Off | Off |
| 011011 | Low-Band Receive Strong Signal | On | Off | On | Off | Off | Off | On | Off | Off |
| 011111 | Low-Band Transmit(Analog only) | On | Off | On | Off | On High Bias | Off | On | Off | Off |
| 111001 | High-Band Receive Normal | On | On | On | On | Off | On | Off | Off | Off |
| 111011 | High-Band Receive Strong Signal | On | On | On | Off | Off | On | Off | Off | Off |
| 110101 | High-Band Transmit (GSM) | On | On | On | Off | Off | Off | Off | On | Off |

NOTE:
 "0" is low logic state; "1" is high logic state.

Dual-band RF front-end

SA1920

OPERATION

The low-band contains both an LNA and mixer that is designed to operate in the 800 to 1000 MHz frequency range. The high-band contains an LNA and image-rejection mixer that is designed to operate in the 1800 to 2000 MHz frequency range with over 30 dB of rejection over an intermediate frequency (IF) range from 100 to 125 MHz.

Image rejection is achieved in the internal architecture by two RF mixers in quadrature and two all-pass filters in the I and Q IF channels that phase shift the IF by 45° and 135°, respectively. The two phase shifted IFs are recombined and buffered to produce the IF output signal.

The LO section consists of an internal all-pass type phase shifter to provide quadrature LO signals to the receive mixers. The all-pass filters outputs are buffered before being fed to the receive mixers. The transmit mixer section consists of a low-noise amplifier, and a down-convert mixer. In the transmit mode, an internal LO buffer is used to drive the transmit IF down-convert mixer.

Low-Band Receive Section

The circuit contains a LNA followed by a wide-band mixer. In a typical application circuit, the LNA output uses an external pull-up inductor to V_{CC} and is AC coupled. The mixer IF outputs are differential. A typical application will load the output buffer with an inductor across the IF outputs, a pull-up inductor to V_{CC} and an AC coupled capacitor to the matching network.

Low-Band Receive Section (Analog Transmit Mode)

The bias current of the low-band LNA will increase during analog transmission, which increases its gain compression point and makes the receiver less sensitive to PA leakage power for an AMPS application.

High-Band Receive Section

The circuit contains an LNA followed by two high dynamic range mixers. These are Gilbert cell mixers; the internal architecture is fully differential. The LO is shifted in phase by 45° and 135° and mixes the amplified RF signal to create I and Q channels. The two I and Q channels are buffered, phase shifted by 45° and 135°, respectively, amplified and recombined internally to realize the image rejection.

The IF output is differential and of the open-collector type. A typical application will load the output buffer with an inductor across the IF outputs, a pull-up inductor to V_{CC} and an AC coupled capacitor to the matching network.

Control Logic Section

Pins HI/LO, SYN ON, Rx On, Tx On, Strong Signal, X2 (doubler) On, control the logic functions. The HI/LO mode selects between low-band and high-band operation. The SYN ON mode enables the LO buffers independent of the other circuitry. When SYN ON is high, all internal buffers in the LO path of the circuit are turned on, thus minimizing LO pulling when the remainder of the receive or transmit chain is powered-up.

The Rx ON mode enables the LO buffers when the device is in the low-band receive normal, receive strong signal and transmit modes; the Rx ON mode enables the LO buffers, also, when the device is in the high-band receive normal, and receive strong signal modes.

The Tx ON mode enables the transmit mixer. The strong signal mode, when disabled, allows the low- and high-band LNAs to function normally; and when the strong signal mode is enabled, it turns-off the low- and high-band LNAs. This is needed when the input signal is large and needs to be attenuated.

The doubler (X2) on mode enables the doubler. When the doubler is on, the input signal from the LO buffers is doubled in frequency. The signal can be used to drive the image-rejection mixer and the output LO high-band ports. When the doubler mode is on, all other control logic (see table 1) functions the same.

Local Oscillator (LO) Section

The LO input directly drives the two internal all-pass networks to provide quadrature LO to the receive mixers. A synthesizer-on (SYN ON) mode is used to power-up all LO input buffers, thus minimizing the pulling effect on the external VCO when entering receive or transmit mode.

Transmit Mixer Section

The transmit mixer is used for down-conversion to the transmit IF. Its inputs are coupled to the transmit RF which is down-converted to a modulated transmit IF frequency, and phase-locked with the baseband modulation.

The IF outputs are HIGH impedance (open-collector type). A typical application will load the output buffer with an inductor across the IF outputs, a pull-up inductor to V_{CC} and AC coupled capacitors to the matching network.

Dual-band RF front-end

SA1920

ABSOLUTE MAXIMUM RATINGS

| QUANTITY | SYMBOL | VALUE | UNIT |
|---|-----------|-------------|------|
| Input supply voltage at pins: 7, 25, 27, 40 | V_{CC} | 4.75 | V |
| Power dissipation | P_D | 150 | mW |
| Input power at all ports | P_{IN} | +20 | dBm |
| Operating temperature range (pin temp) | T_O | -40 to +85 | °C |
| Storage temperature range | T_{srg} | -65 to +125 | °C |

DC ELECTRICAL CHARACTERISTICS

Unless otherwise specified, all Input/Output ports are single-ended.

DC PARAMETERS

$V_{CC} = +3.75$ V, $T_A = -40$ to $+85$ °C unless otherwise noted

| QUANTITY | CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|-----------|----------|------|------|------|------|
| DC Supply voltage | | V_{CC} | 3.6 | 3.75 | 3.9 | V |
| Current Consumption: Sleep Mode | X000XX | I_{CC} | | 1 | 100 | μA |
| Low Band Receive Normal | 011000 | I_{CC} | 10.1 | 12.5 | 15.2 | mA |
| Low Band Receive Strong | 011010 | I_{CC} | | 8.8 | | mA |
| Low Band Transmit (Analog) | 011110 | I_{CC} | | 18.0 | | mA |
| Low Band Transmit (GSM) | 010100 | I_{CC} | | 16.0 | | mA |
| High Band Receive Normal | 111000 | I_{CC} | 35.0 | 42.0 | 53.0 | mA |
| High Band Receive Strong | 111010 | I_{CC} | | 38.0 | | mA |
| High Band Transmit (GSM) | 110100 | I_{CC} | | 21.5 | | mA |
| Frequency Doubler | | | | 8.8 | | mA |
| Logic Low Input | | | 0 | | 0.5 | V |
| Logic High Input | | | 1.9 | | 4.0 | V |

Dual-band RF front-end

SA1920

AC ELECTRICAL CHARACTERISTICS**Low-Band, Dual Mode of Operation**

$V_{CC} = +3.75$ V, $Freq_{RF} = 881$ MHz, $Freq_{LO} = 991.52$ MHz, $P_{in} = -3$ dBm, $T_A = +25^\circ$ C; unless otherwise stated

| PARAMETERS | Min | -3 σ | TYP | +3 σ | Max | UNITS | NOTES |
|---|------|-------------|--------|-------------|------|-----------|-------|
| System | | | | | | | |
| RF Input Frequency Range | 869 | | 881 | | 960 | MHz | |
| IF Frequency | | | 110.52 | | | MHz | |
| LO Frequency | | | 991.52 | | | MHz | |
| Cascaded Power Gain; includes 3dB filter loss | 22.5 | | 24 | | 25.5 | dB | |
| Power Gain Reduction (Strong Signal Mode—LNA Off) | 29 | | 35 | | 41 | dB | |
| Cascaded Noise Figure; includes 3dB filter loss | | | 2.6 | | | dB | |
| LNA | | | | | | | |
| LNA Gain | | 17 | 17.5 | 18 | | dB | |
| LNA IIP3 | | -6 | -5 | -4 | | dBm | |
| LNA Noise Figure | | 1.6 | 1.7 | 1.8 | | dB | |
| Mixer | | | | | | | |
| Mixer Gain | | 9 | 9.5 | 10 | | dB | |
| Mixer IIP3 | | 4 | 5 | 6 | | dBm | |
| Mixer Noise Figure | | 9 | 10 | 11 | | dB | |
| Other | | | | | | | |
| Input Impedance, RF Port | | | 50 | | | Ω | |
| Return Loss at LNA Inputs and Output | | | | | -10 | dB | 1 |
| Return Loss at Mixer Input and Outputs | | | | | -10 | dB | 1 |
| LO leakage at RF Port | | | -42 | | | dBm | |
| LO Input Power | -5 | | -3 | | -1 | dBm | |
| Turn ON/OFF Time | | | 100 | | | μ sec | |

Low-Band LO Buffer

| PARAMETERS | Min | -3 σ | TYP. | +3 σ | Max | UNITS | NOTES |
|-------------------------------|-----|-------------|--------|-------------|-----|-----------|-------|
| LO Frequency | | | 991.52 | | | MHz | |
| Differential Output Power | | | -7 | | | dBm | |
| Differential Output Impedance | | | 100 | | | Ω | |
| Harmonic Content | | | -20 | | | dBc | |
| Input Power | -5 | | -3 | | -1 | dBm | |
| Input Impedance | | | 50 | | | Ω | 1 |
| Turn On/Off Time | | | 30 | | | μ sec | |

Dual-band RF front-end

SA1920

AC ELECTRICAL CHARACTERISTICS

High-Band, Single Mode of Operation
LNA and Image Reject Mixer $V_{CC} = +3.75$ V, $Freq_{RF} = 1960$ MHz, $Freq_{LO} = 2070.52$ MHz, $P_{in} = -3$ dBm, $T_A = +25^\circ$ C; unless otherwise stated

| PARAMETERS | MIN | -3 σ | TYP. | +3 σ | MAX | UNITS | NOTES |
|---|------|-------------|--------|-------------|------|-----------|-------|
| RF Input Frequency Range | 1805 | | | | 1990 | MHz | |
| IF Frequency | 100 | | 110.52 | | 125 | MHz | |
| LO Frequency | 1905 | | | | 2115 | MHz | |
| Power Gain | 21 | | 23.5 | | 25 | dB | |
| Power Gain Reduction (Strong Signal Mode—LNA Off) | 40 | | 47 | | 54 | dB | |
| Noise Figure | | 4.0 | 4.2 | 4.4 | | dB | |
| Input Impedance, RF Port | | | 50 | | | Ω | |
| Return Loss at Inputs | | | | | -10 | dB | 1 |
| LO leakage at RF Port | | | -48 | | | dBm | |
| 1 dB RF Input Compression Point | | | -24 | | | dBm | |
| IP3 (3 RD Order Intermodulation Product) Referred to the RF Input Port | | -15 | -12.5 | -10 | | dBm | |
| (2 x LO) – (2 x RF) Spur Performance -50 dBm IN Referred to RF Input Port Measure at LO = 2040 MHz and RF = 1985 MHz | | | -65 | | | dBc | |
| (3 x LO) – (3 x RF) Spur Performance. -50 dBm IN Referred to RF Input Port. Measure at LO = 2040 MHz and RF = 2003 MHz. | | | -62.5 | | | dBc | |
| Image rejection, $f_{RX}+2f_{IF}$ or $f_{RX}-2f_{IF}$ Referred to the RF Input Port | 30 | | 35 | | | dB | |
| LO Input Power | -5 | | -3 | | -1 | dBm | |
| Turn ON/OFF Time | | | 30 | | | μ sec | |

High-Band LO Buffer

| PARAMETERS | MIN | -3 σ | TYP. | +3 σ | MAX | UNITS | NOTES |
|-------------------------------|------|-------------|------|-------------|------|-----------|-------|
| LO Frequency Range | 1905 | | | | 2115 | MHz | |
| Differential Output Power | | | -9 | | | dBm | |
| Differential Output Impedance | | | 100 | | | Ω | |
| Harmonic Content | | | | | -20 | dBc | |
| Input Power | -5 | | -3 | | -1 | dBm | |
| Input Impedance | | | 50 | | | Ω | 1 |
| Turn On/Off Time | | | 30 | | | μ sec | |

Dual-band RF front-end

SA1920

Frequency Doubler

| PARAMETERS | MIN | -3 σ | TYP. | +3 σ | MAX | UNITS | NOTES |
|--|------|-------------|------|-------------|------|-----------|-------|
| Output Frequency Range | 1905 | | | | 2115 | MHz | |
| Output Power | | | -9 | | | dBm | |
| Differential Output Impedance | | | 100 | | | Ω | |
| Harmonic Content (3F, 4F, etc.) | | | -20 | | | dBc | |
| Subharmonic Content (F _i) | | | -20 | | | dBc | |
| Non-Harmonic Content | | | 80 | | | dBc | |
| Turn On/Off Time | | | 30 | | | μ sec | |
| Phase Noise Degradation, $\Delta f = 30$ kHz | | | 6 | | | dB | |

Transmit Mixer

| PARAMETERS | MIN | -3 σ | TYP. | +3 σ | MAX | UNITS | NOTES |
|--|-----|-------------|------|-------------|------|----------|-------|
| T _X Mixer Input Frequency | 824 | | | | 1910 | MHz | |
| T _X RF Input Impedance, Balanced | | | 200 | | | Ω | |
| T _X Mixer Output Frequency | 70 | | | | 200 | MHz | |
| T _X IF Load Impedance | | | 1000 | | | Ω | |
| Maximum T _X IF Load Capacitance | | | | | 2 | pF | |
| Conversion Power Gain | | 15 | 16 | 17 | | dB | 2 |
| 1 dB Input Compression Point | | | -17 | | | dBm | |
| IIP2 | | | 20 | | | dBm | |
| IIP3 | | -9 | -7 | -5 | | dBm | |
| Noise Figure (double sideband) | | | 7.5 | | | dB | |
| Reverse Isolation T _{XIN} -L _{OIN} | 40 | | | | | dB | |
| Isolation L _{OIN} -T _{XIN} | 40 | | | | | dB | |

NOTES:

- External matching network is required.
- From 200 Ω input to a 1k Ω output.

Dual-band RF front-end

SA1920

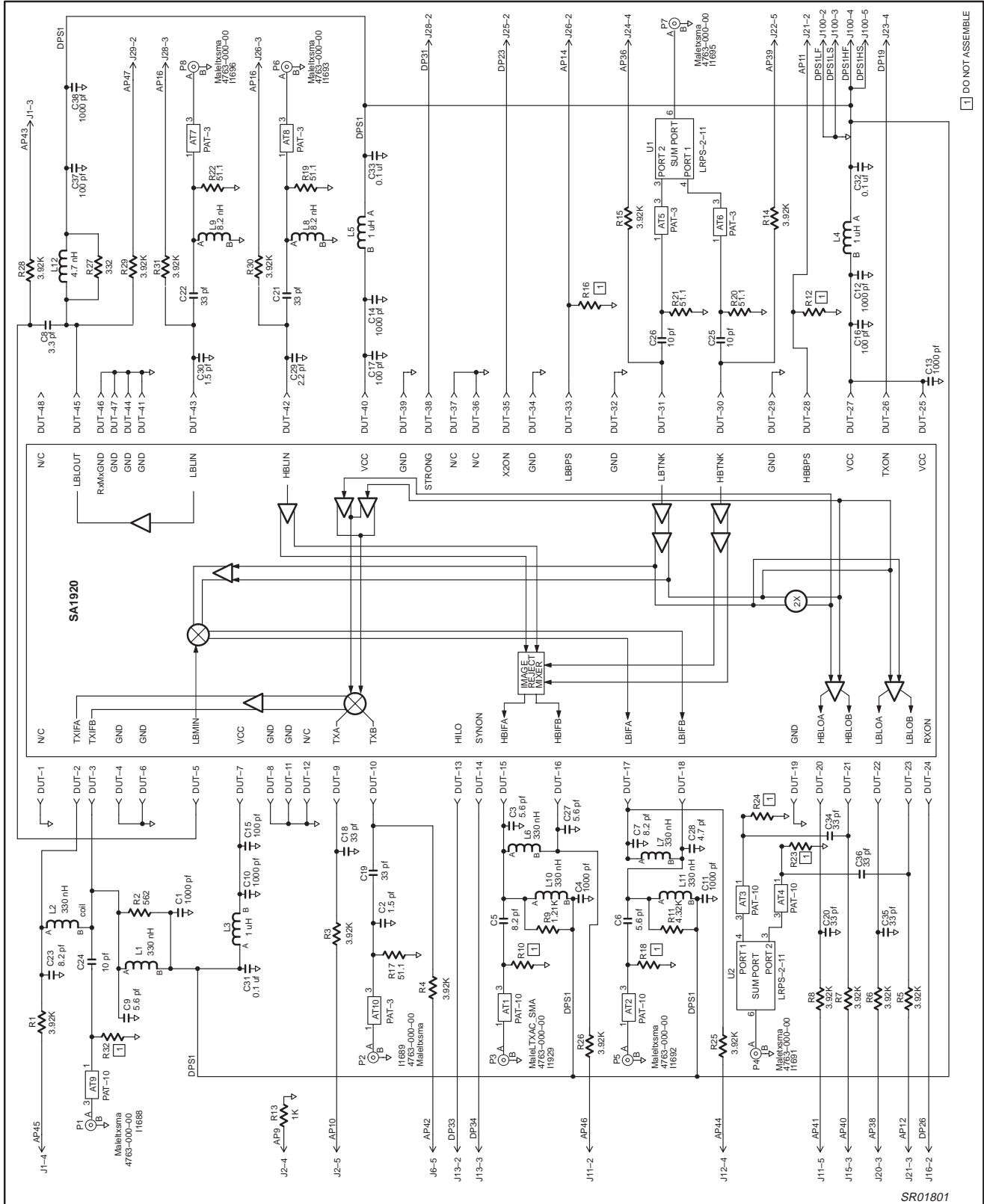


Figure 3. SA1920 Dual-Band Test Circuit

Dual-band RF front-end

SA1920

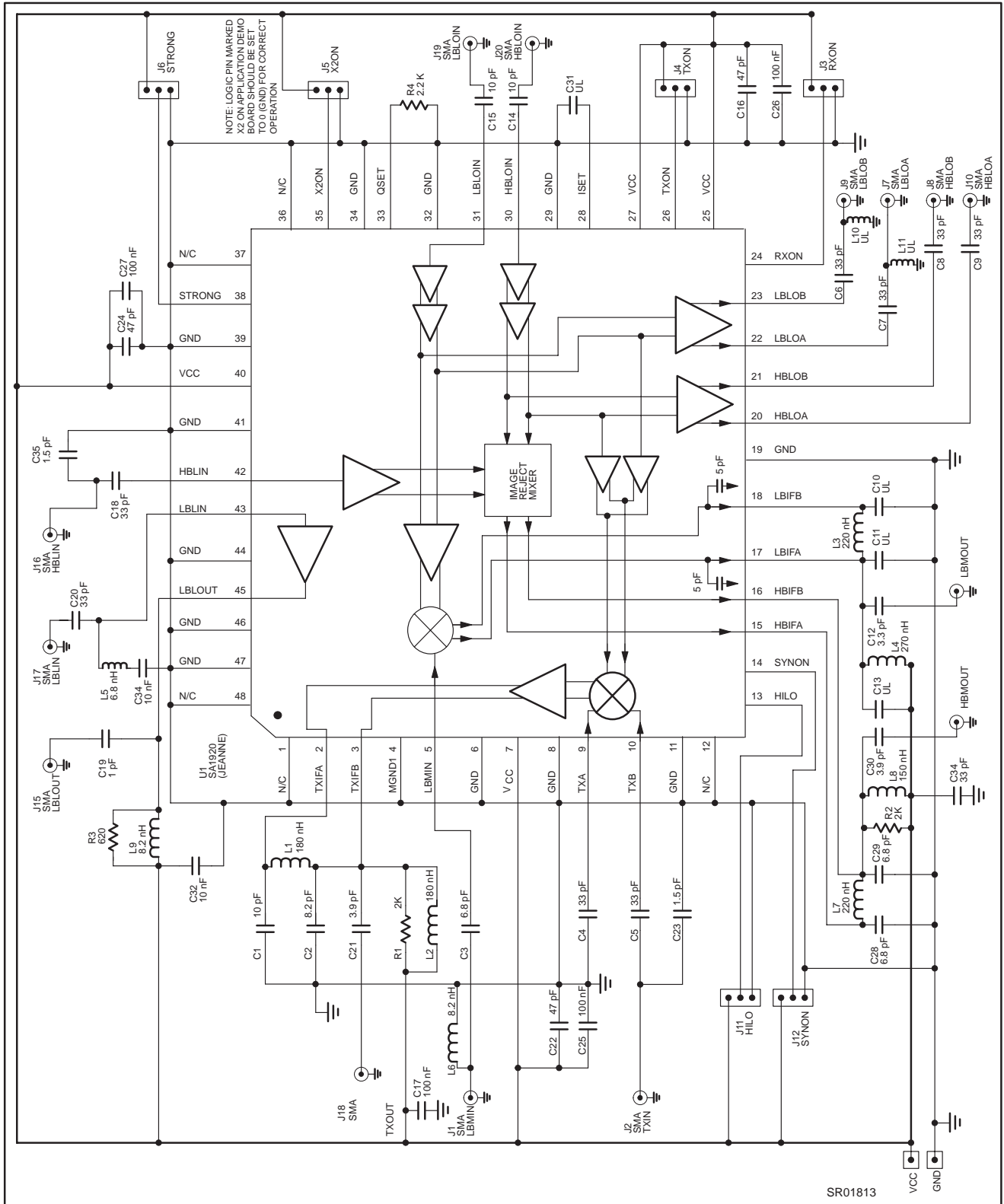


Figure 4. SA1920 Dual-Band Application Circuit

Dual-band RF front-end

SA1920

PERFORMANCE CHARACTERISTICS

$V_{CC} = +3.75$ V, $Freq_{RF} = 1960$ MHz, $Freq_{LO} = 2070.52$ MHz, $P_{in} = -5$ dBm, $T_A = +25^\circ\text{C}$; unless otherwise stated

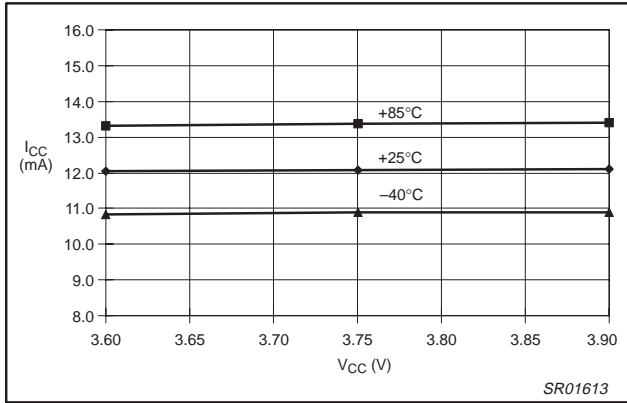


Figure 5. Low Band Receive Normal ICC

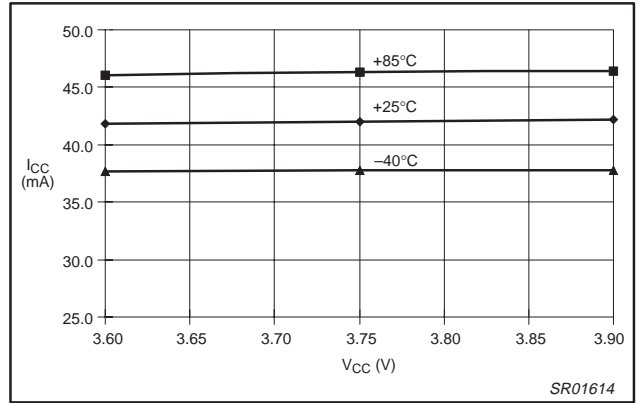


Figure 6. High Band Receive Normal ICC

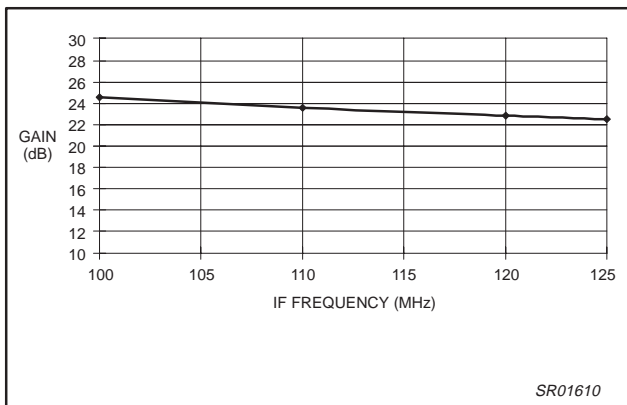


Figure 7. High Band Gain vs. IF Frequency

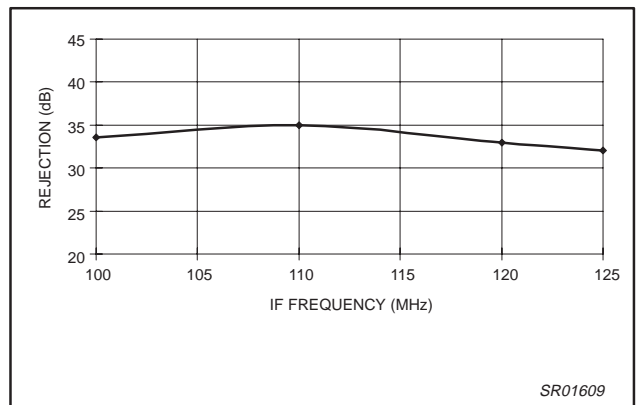


Figure 8. High Band Image Rejection vs. IF Frequency

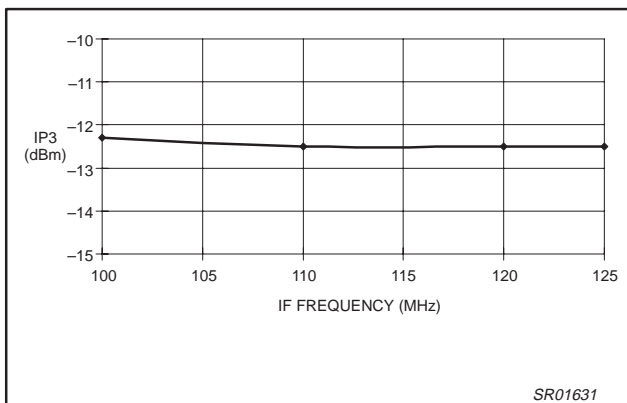


Figure 9. High Band IP3 vs. IF Frequency

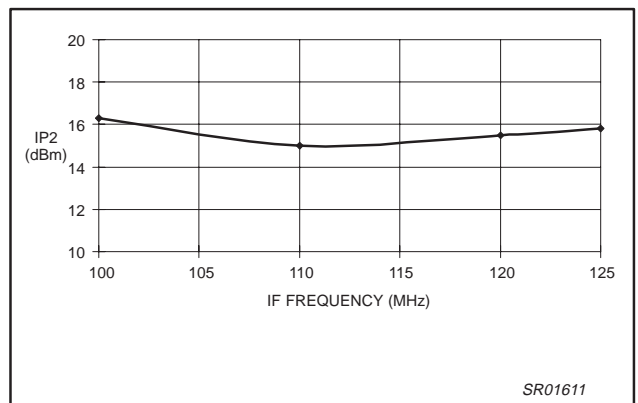


Figure 10. High Band IP2 vs. IF Frequency

Dual-band RF front-end

SA1920

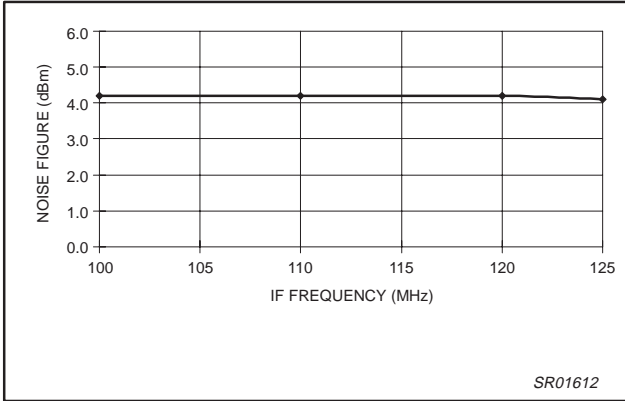


Figure 11. High Band NF vs. IF Frequency

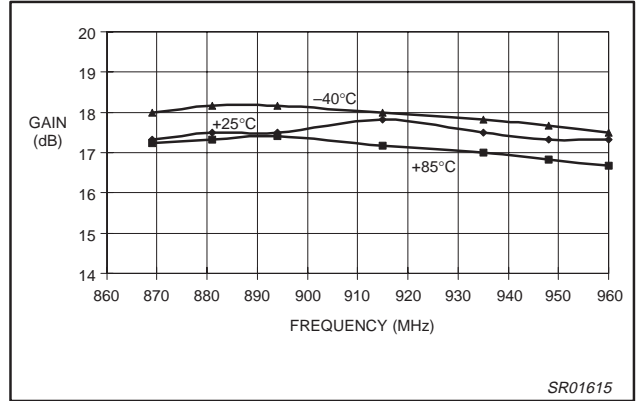


Figure 12. LB LNA Gain vs. Frequency

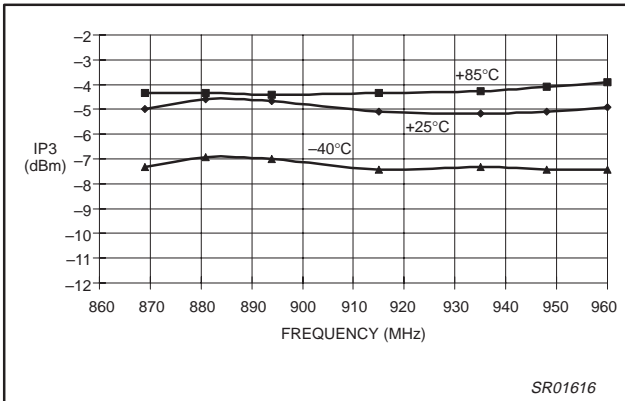


Figure 13. LB LNA IP3 vs. Frequency

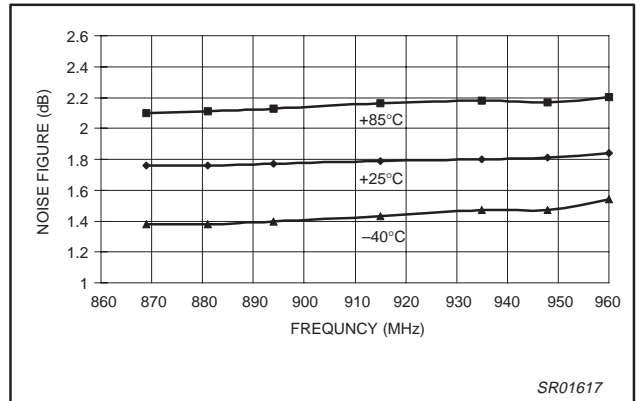


Figure 14. LB LNA Noise Figure vs. Frequency

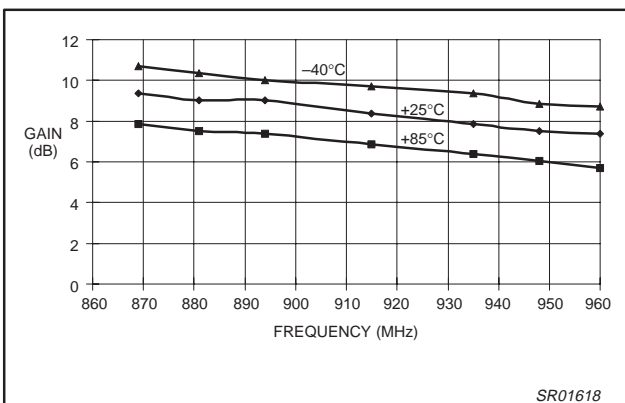


Figure 15. LB Mixer Gain vs. Frequency

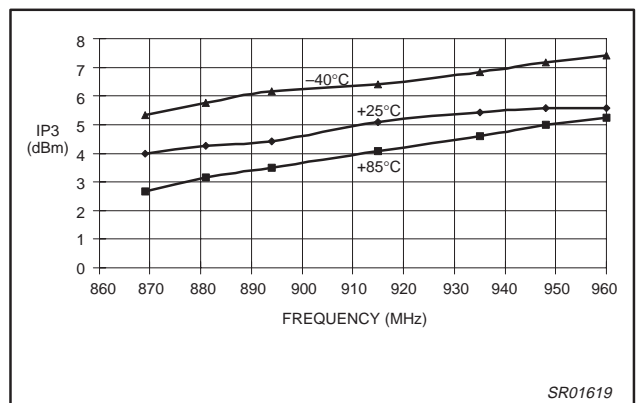


Figure 16. LB Mixer IP3 vs. Frequency

Dual-band RF front-end

SA1920

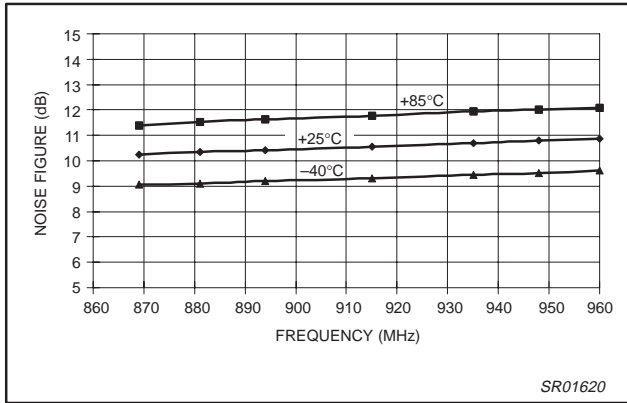


Figure 17. LB Mixer Noise Figure vs. Frequency

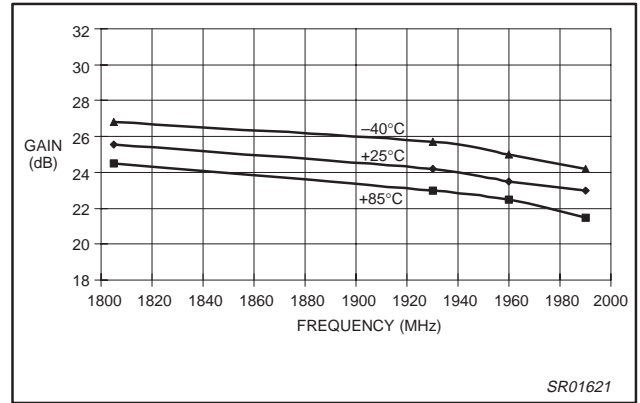


Figure 18. HB Gain vs. Frequency

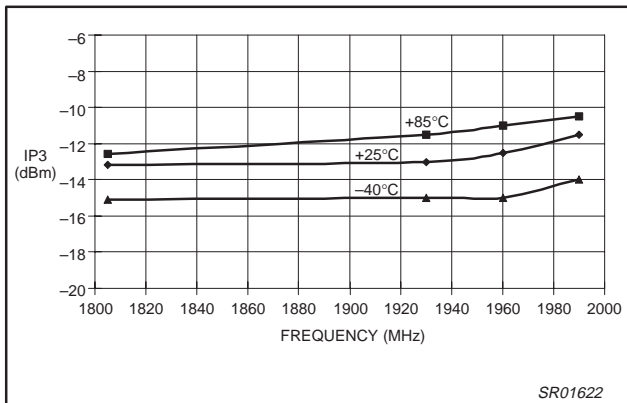


Figure 19. HB IP3 vs. Frequency

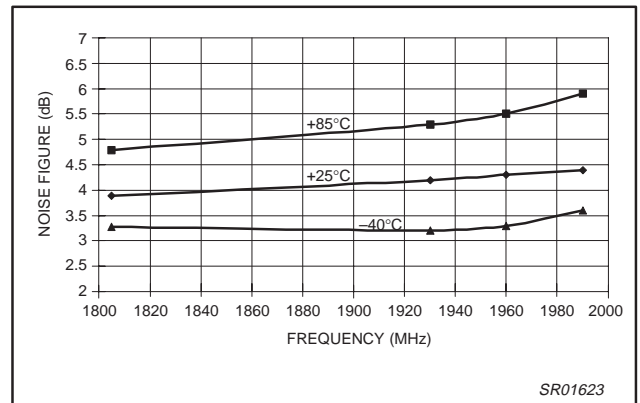


Figure 20. HB Noise Figure vs. Frequency

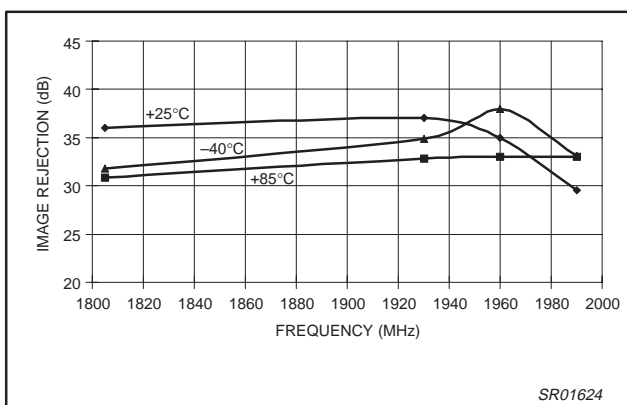


Figure 21. HB Image Rejection vs. Frequency

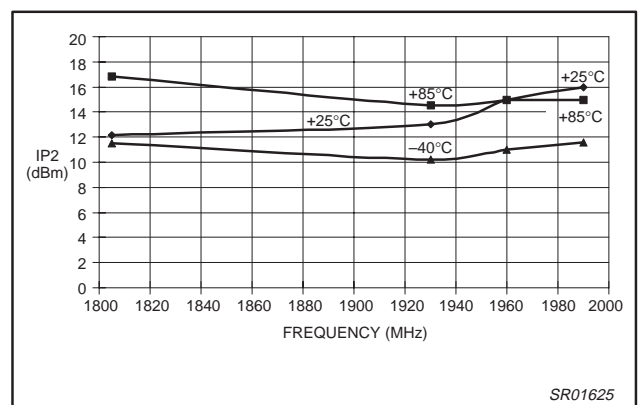


Figure 22. HB IP2 vs. Frequency

Dual-band RF front-end

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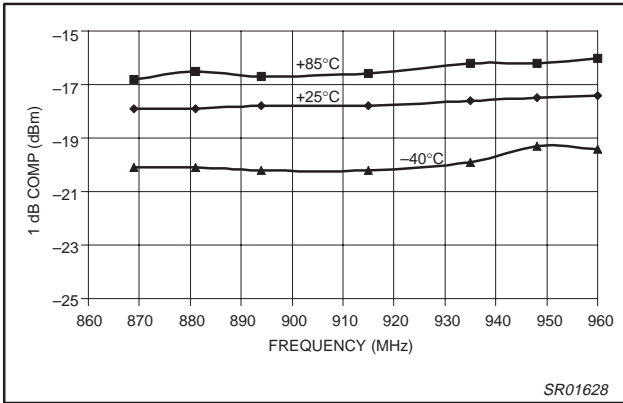


Figure 23. LB LNA 1 dB Compression vs. Frequency

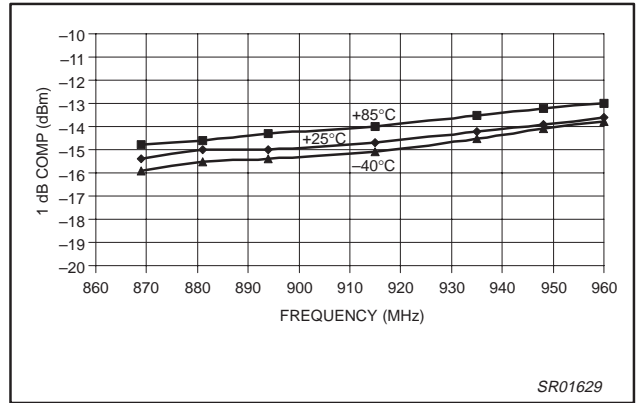


Figure 24. LB Mixer 1 dB Compression vs. Frequency

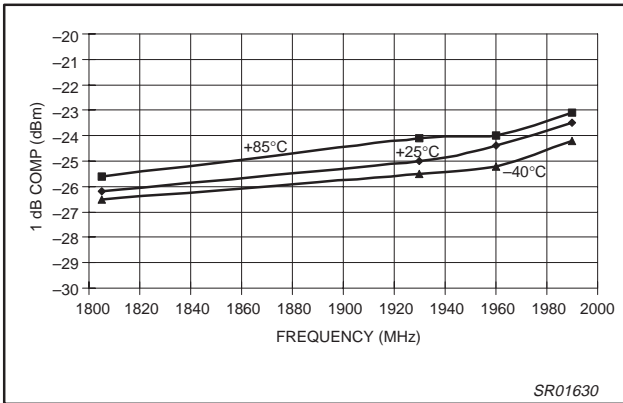


Figure 25. HB 1 dB Compression vs. Frequency

Dual-band RF front-end

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S-PARAMETERS

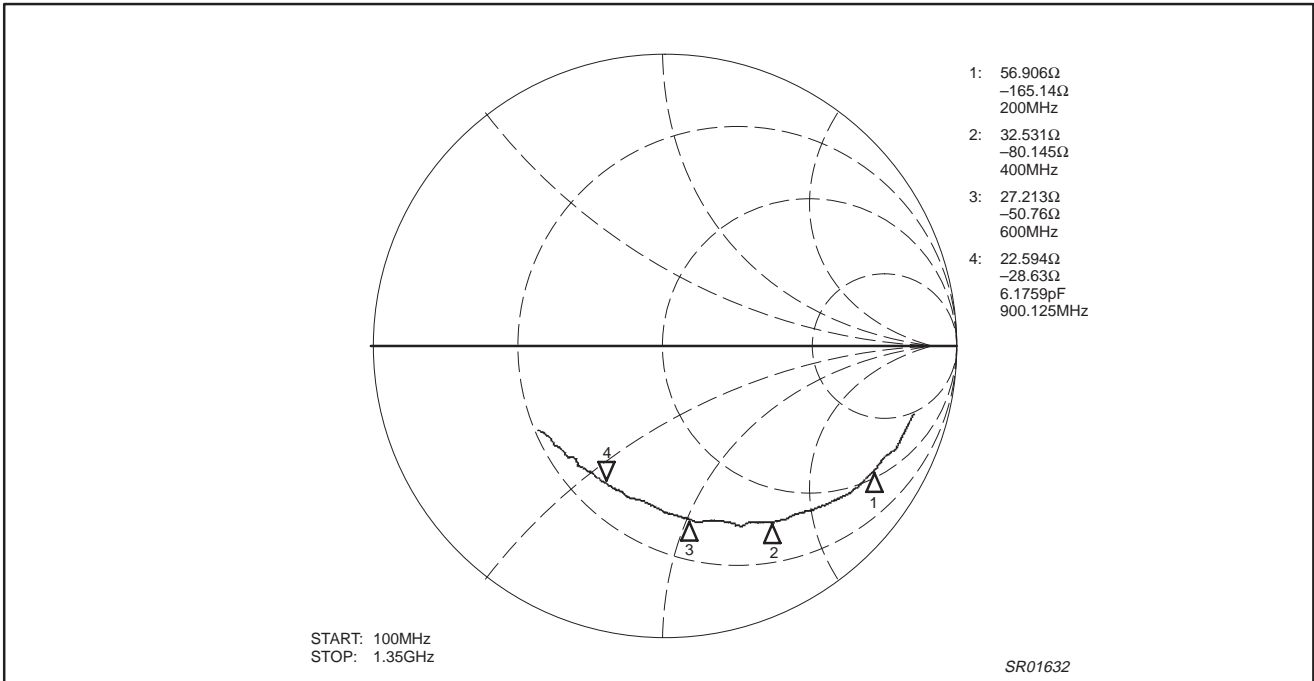


Figure 26. Typical S_{11} of the Low Band LNA at 3.75 V for the Low Band Receive Normal Mode

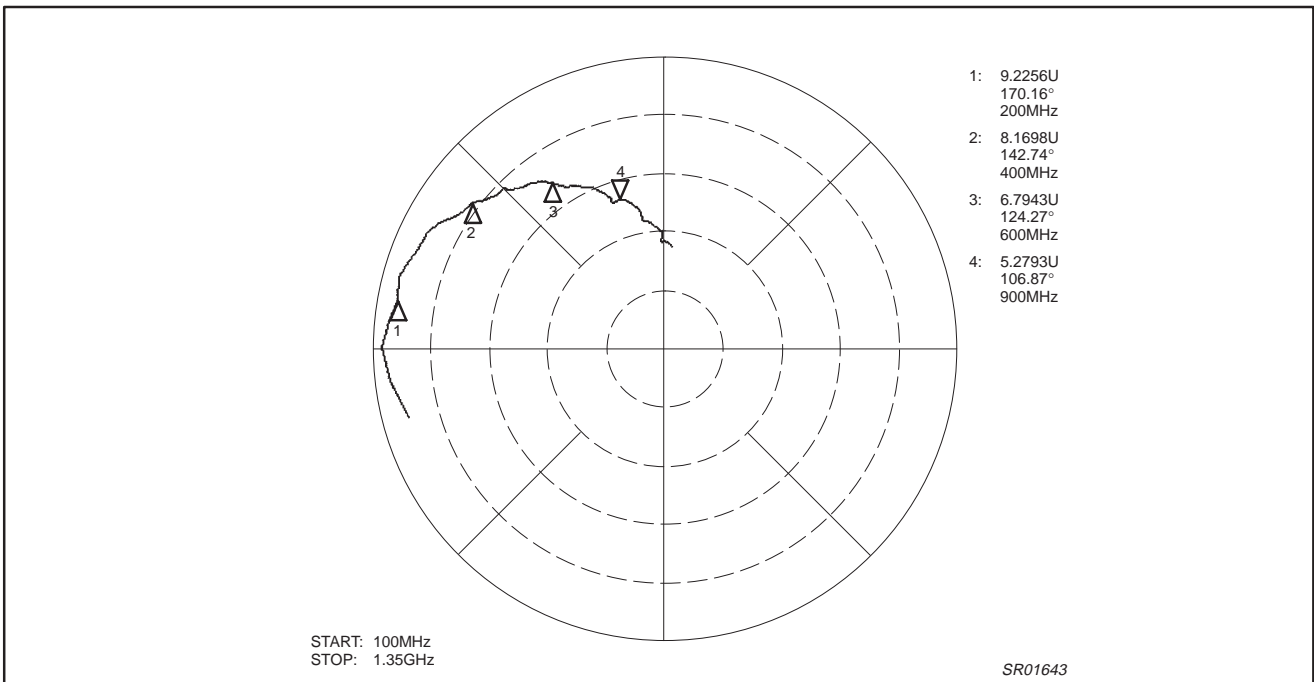


Figure 27. Typical S_{21} of the Low Band LNA @ 3.75V for the Low Band Receive Normal Mode

Dual-band RF front-end

SA1920

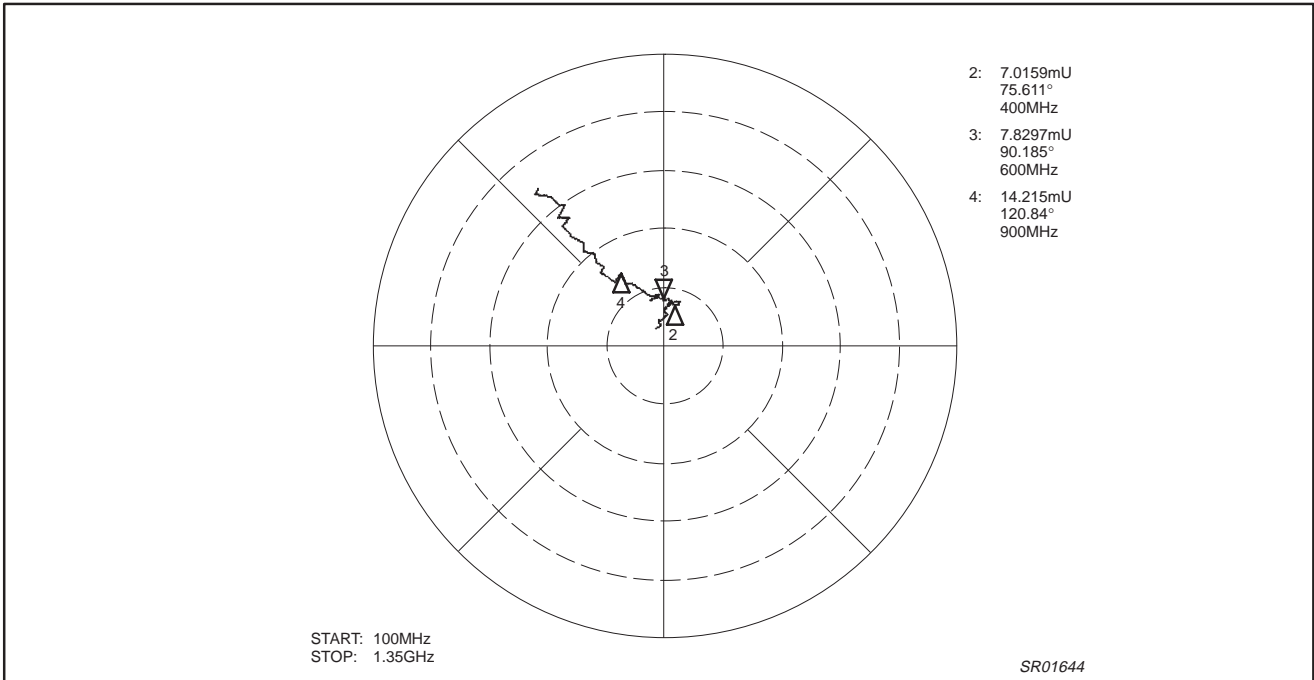


Figure 28. Typical S_{12} of the Low Band LNA @ 3.75V for the Low Band Receive Normal Mode

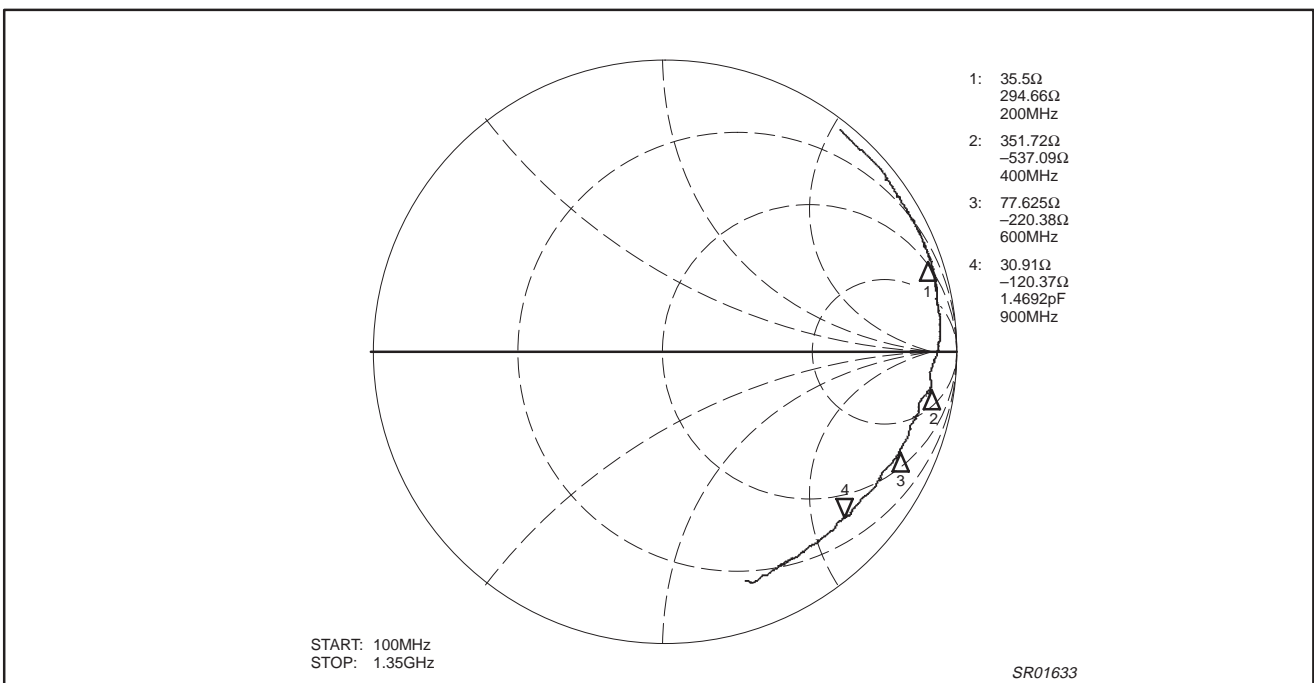


Figure 29. Typical S_{22} of the Low Band LNA @ 3.75V for the Low Band Receive Normal Mode

Dual-band RF front-end

SA1920

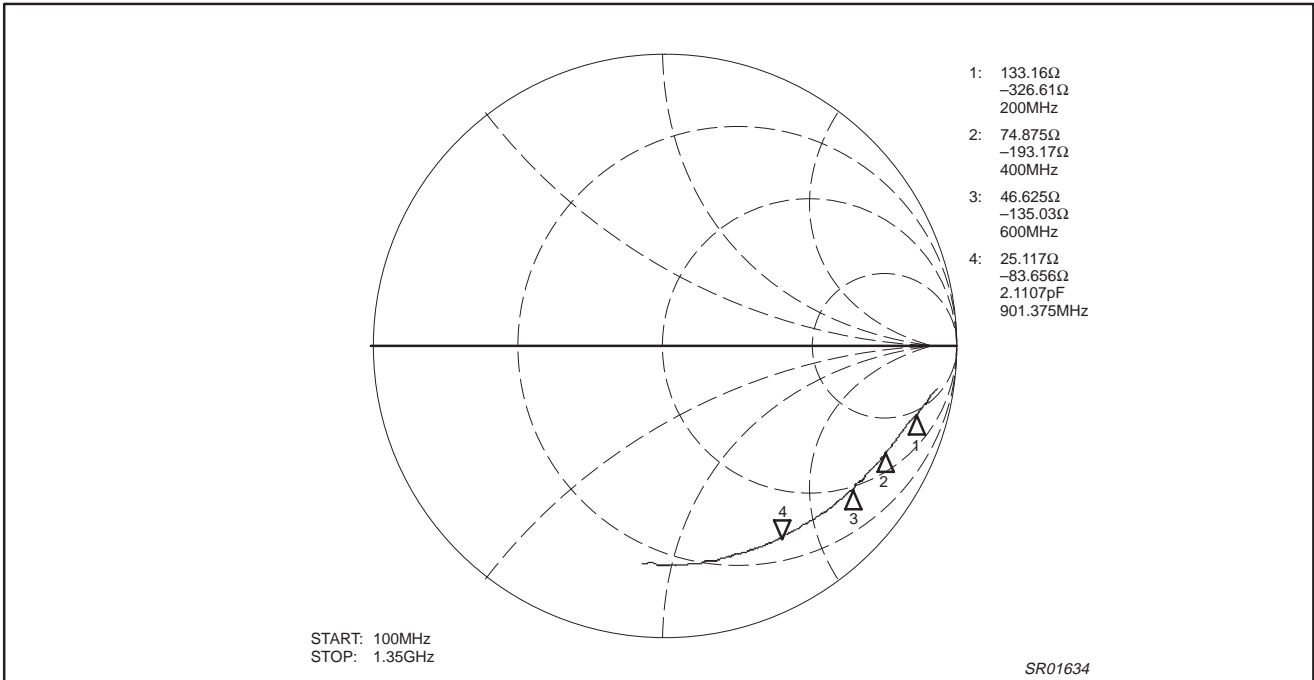


Figure 30. Typical S_{11} of Low Band LNA @ 3.75V for Receive Strong Signal Mode

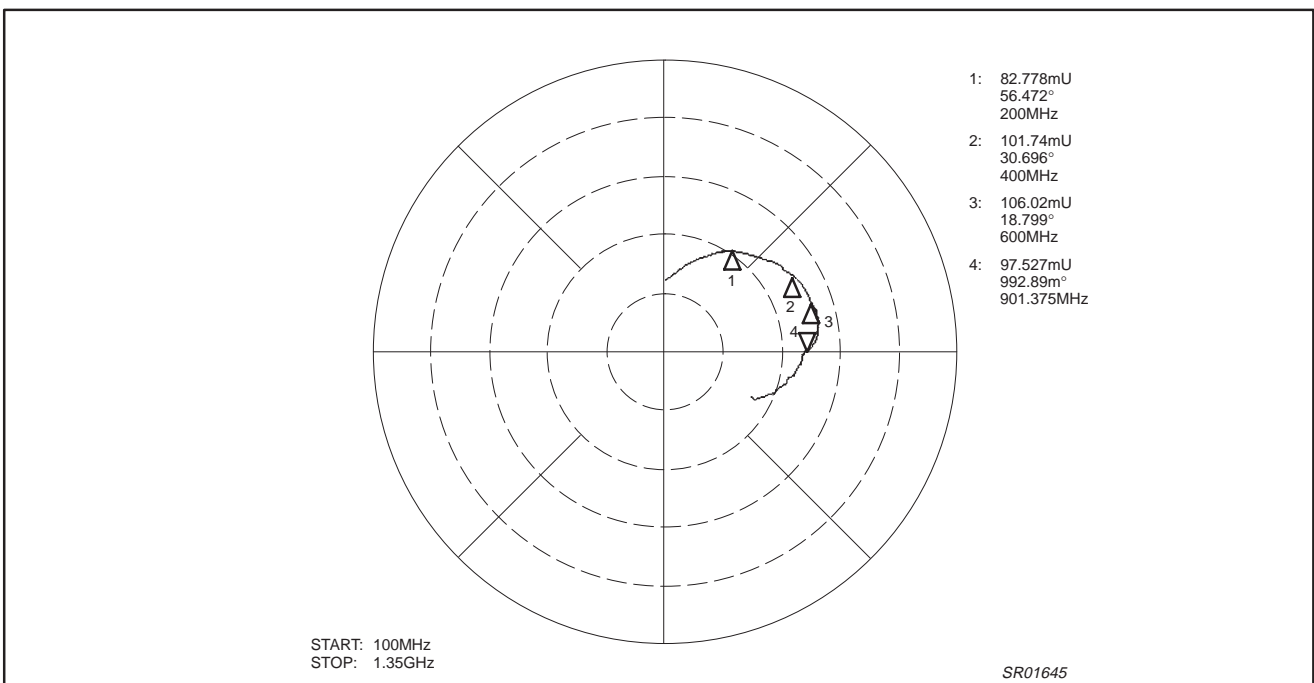


Figure 31. Typical S_{21} of the Low Band LNA @ 3.75V for Receive Strong Signal Mode

Dual-band RF front-end

SA1920

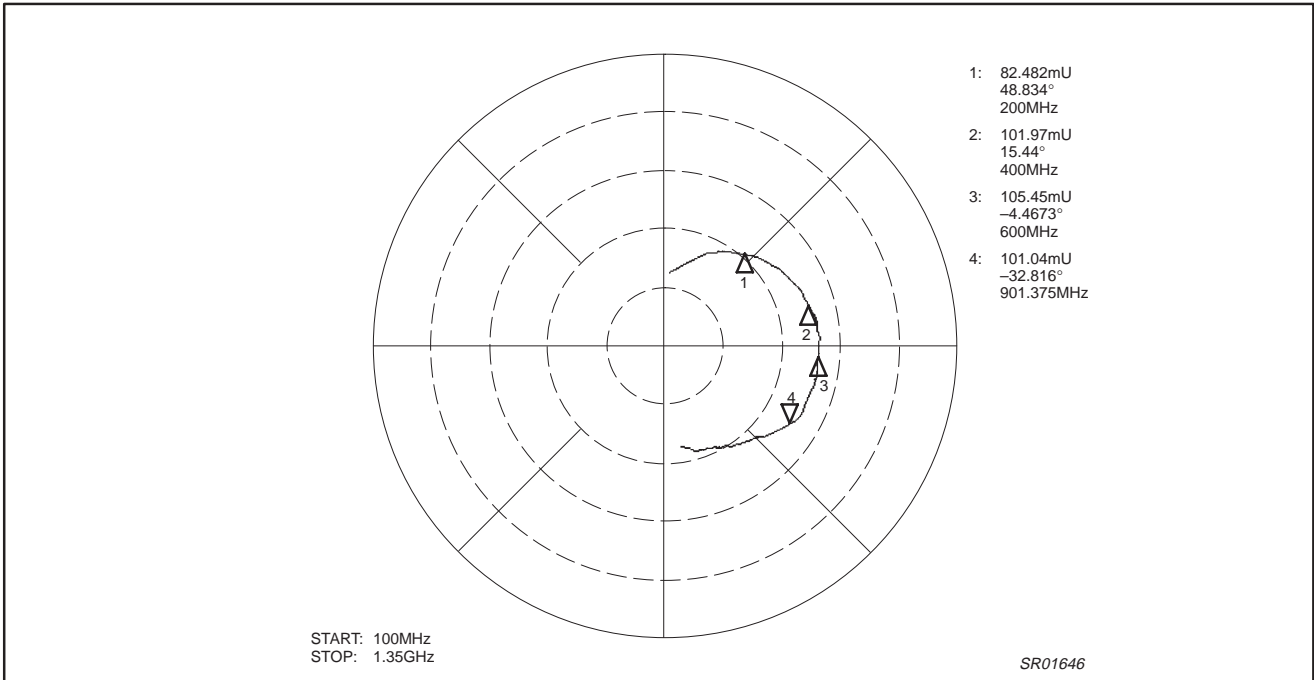


Figure 32. Typical S_{12} for the Low Band LNA @ 3.75V for the Receive Strong Signal Mode

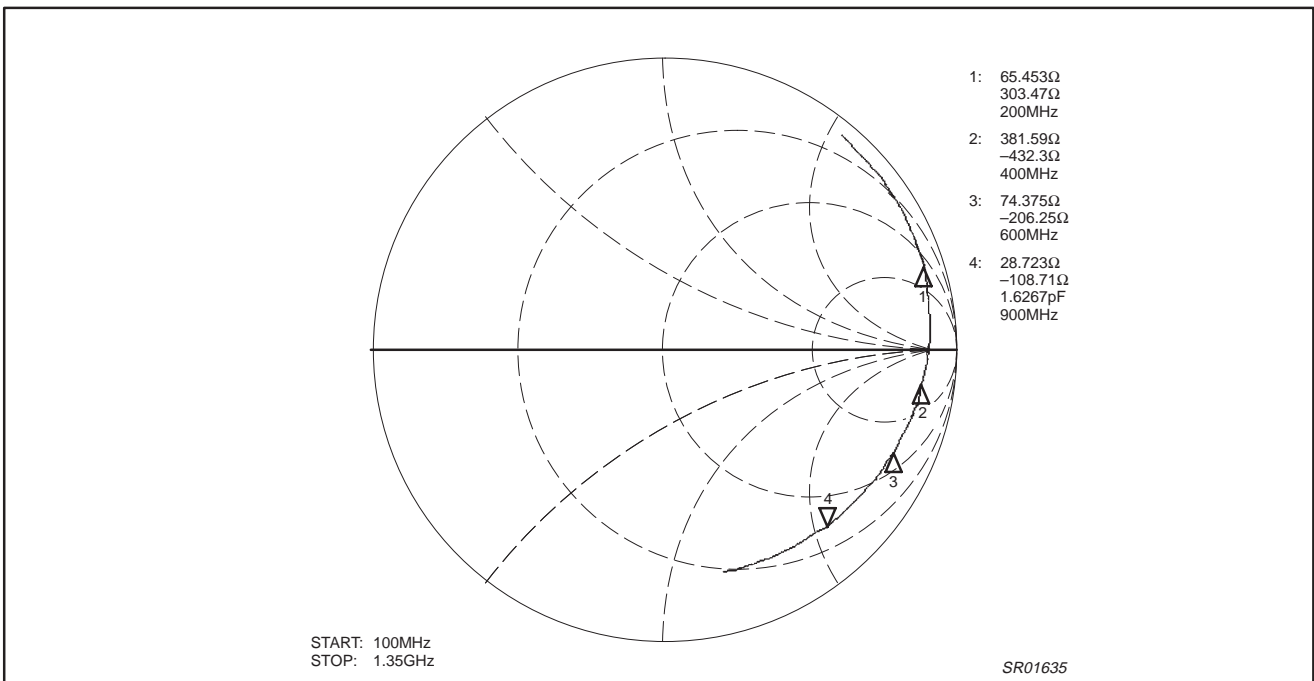


Figure 33. Typical S_{22} for the Low Band LNA @ 3.75V for the Strong Receive Signal Mode

Dual-band RF front-end

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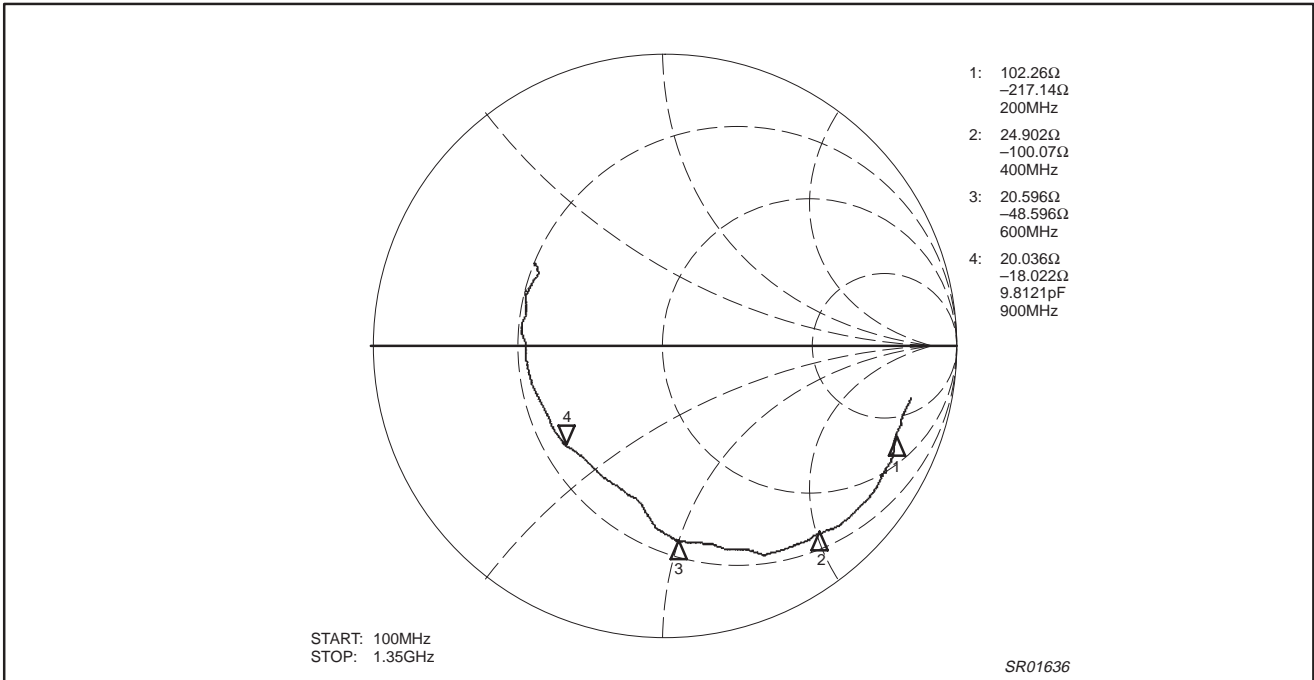


Figure 34. Typical S_{11} for the Low Band Mixer @ 3.75V for the Receive Normal Mode

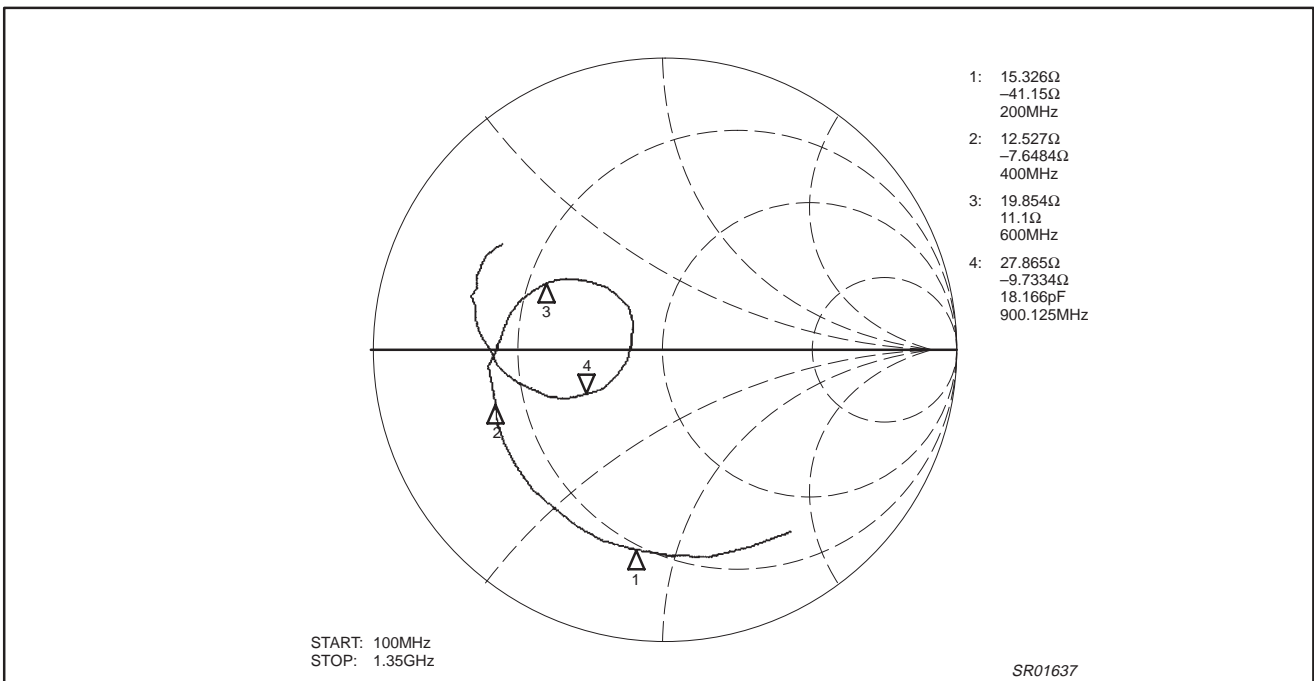


Figure 35. Typical S_{11} for the Low Band LO @ 3.75V for the Low Band Receive Normal Mode

Dual-band RF front-end

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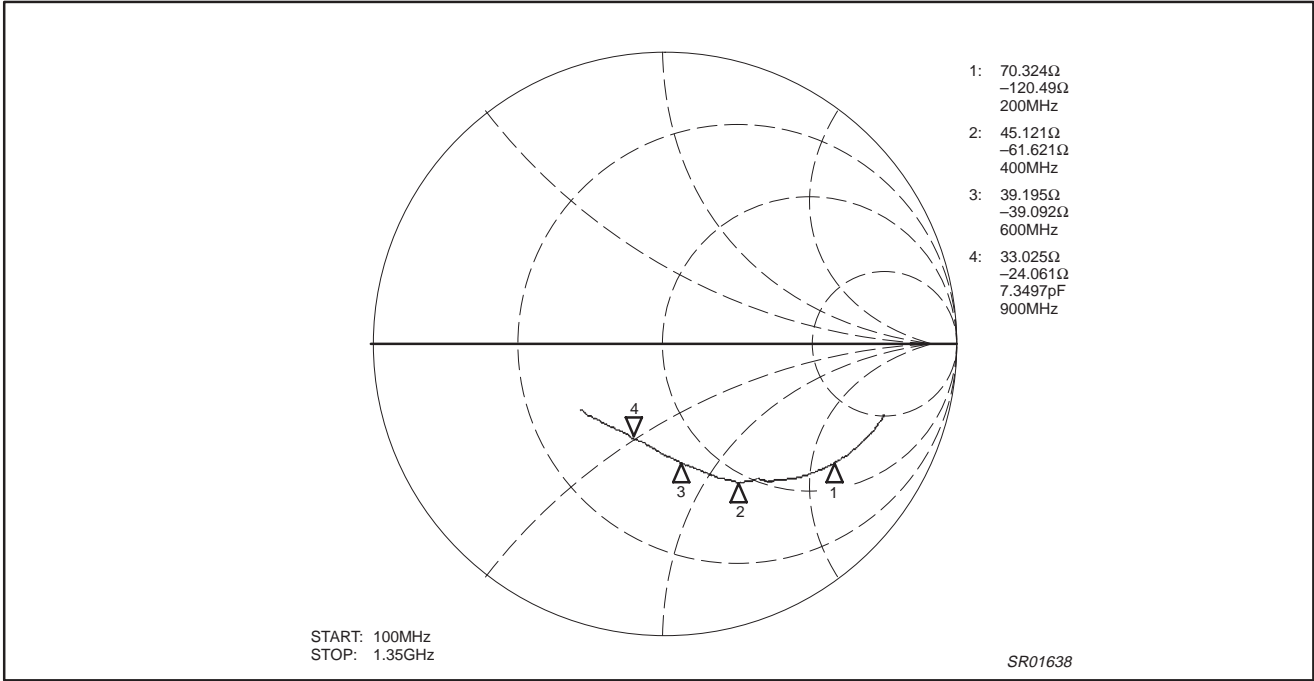


Figure 36. Typical S_{11} for the Low Band LNA @ 3.75V for the Low Band Transmit (Analog) Mode

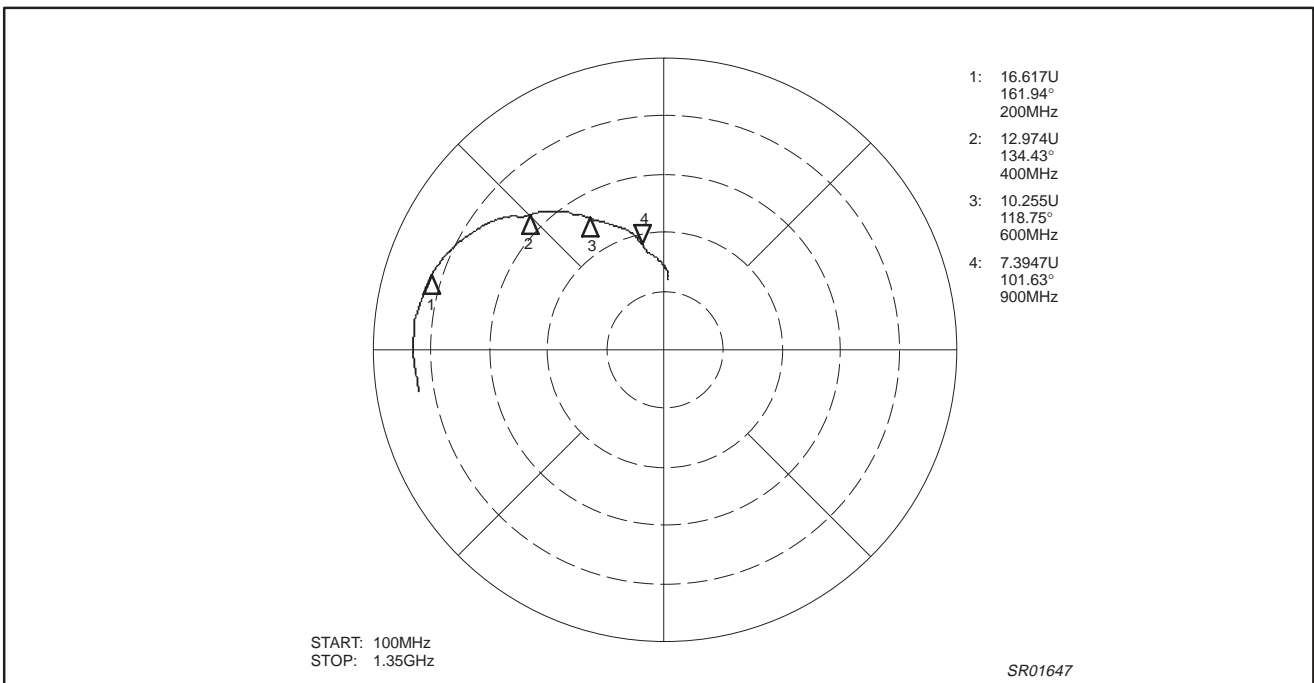


Figure 37. Typical S_{21} of the Low Band LNA @ 3.75V for the Low Band Transmit (Analog) Mode

Dual-band RF front-end

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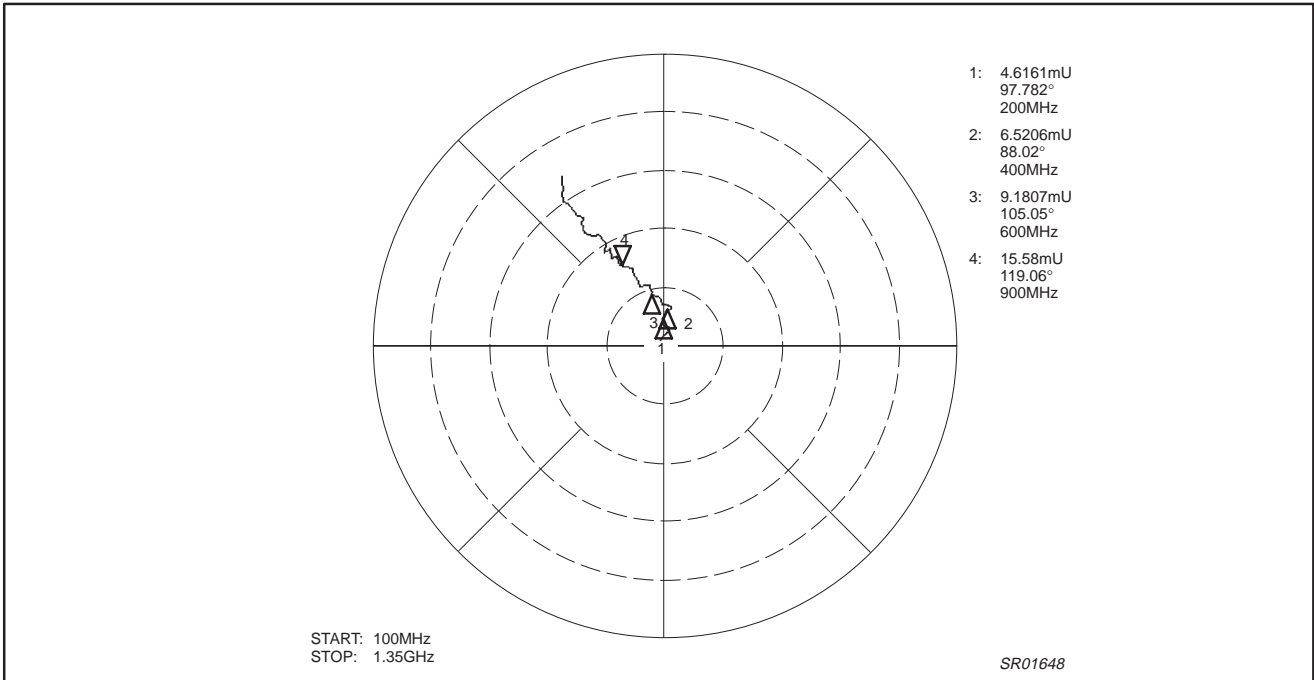


Figure 38. Typical S_{12} for the Low Band LNA @ 3.75V for the Low Band Transmit (Analog) Mode

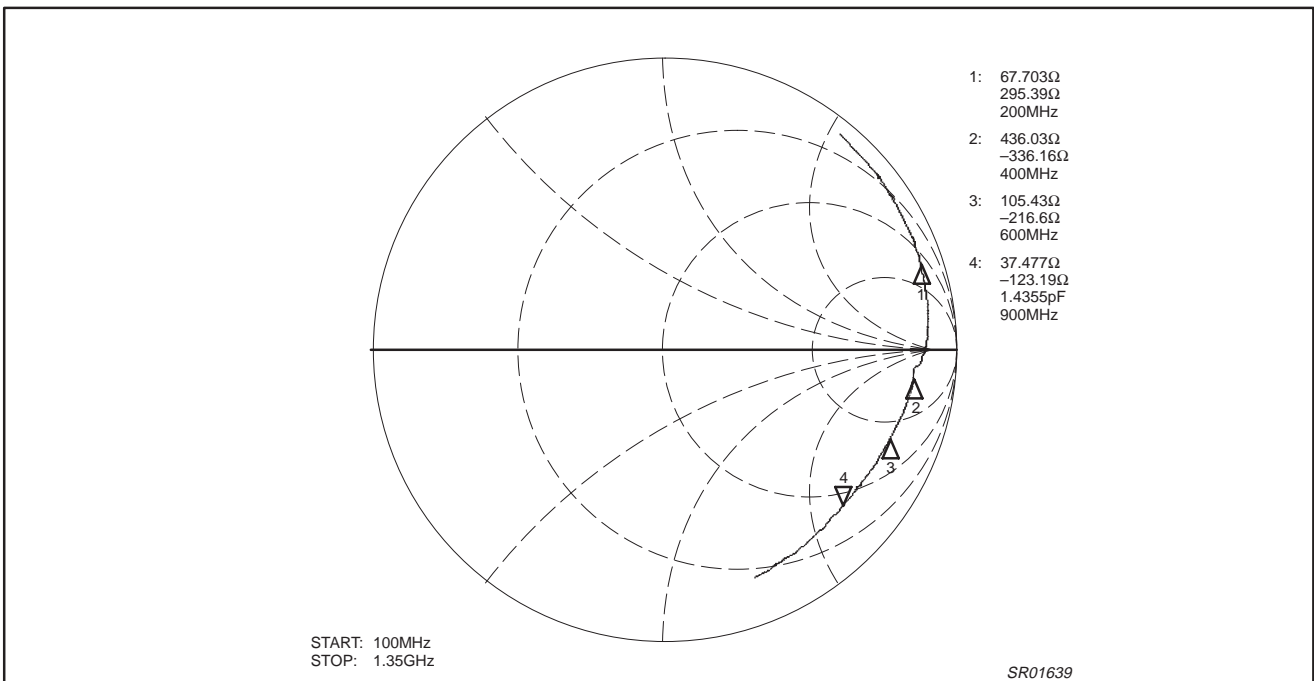


Figure 39. Typical S_{22} for the Low Band LNA @ 3.75V for the Low Band Transmit (Analog) Mode

Dual-band RF front-end

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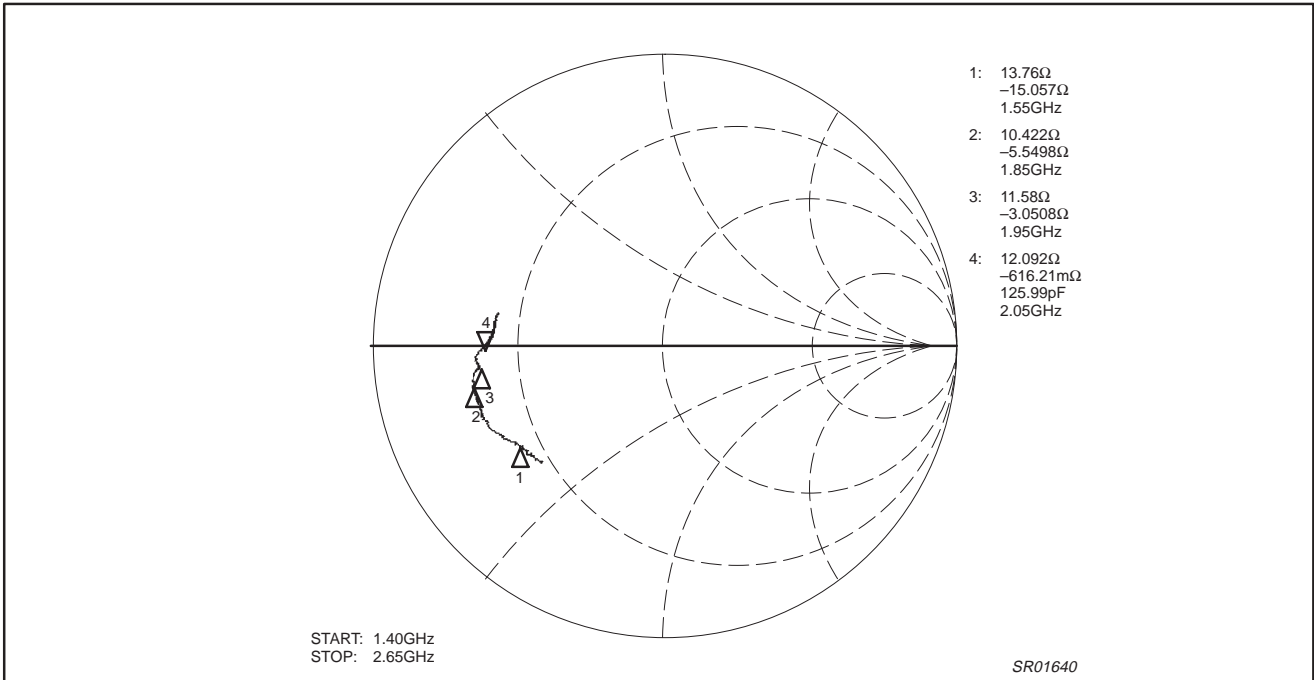


Figure 40. Typical S_{11} for the High Band LNA @ 3.75V for the High Band Receive Normal Mode

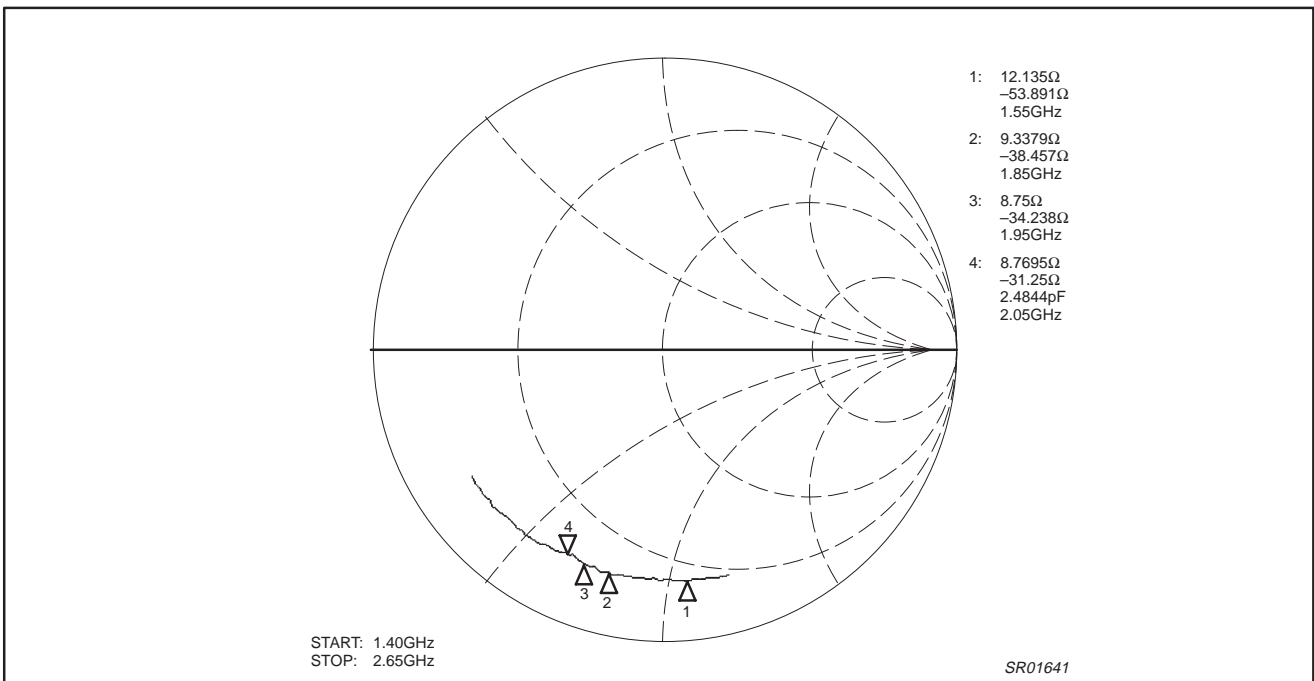


Figure 41. Typical S_{11} for the High Band LNA @ 3.75V for the High Band Receive Strong Signal Mode

Dual-band RF front-end

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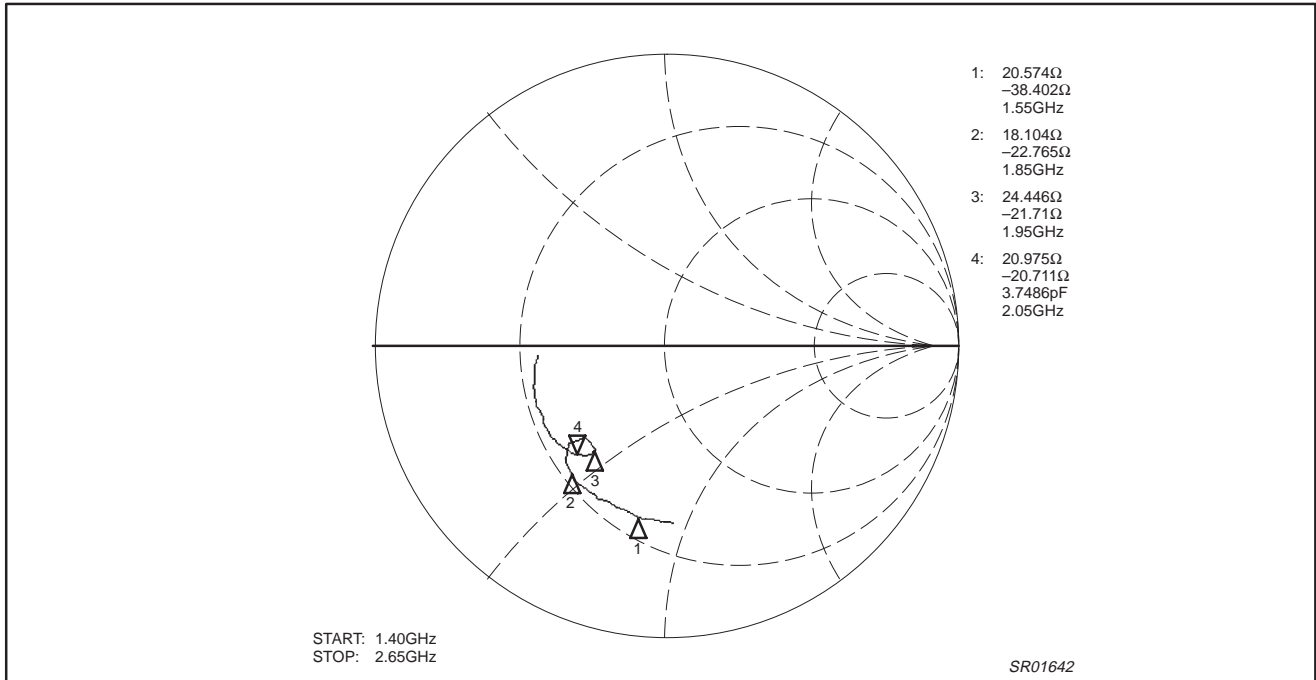


Figure 42. Typical S_{11} of the High Band LO @ 3.75V for the High Band Receive Normal Mode

Dual-band RF front-end

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Table 2. Typical S-Parameters of Low Band LNA at $V_{CC} = +3.75V$, LB Receive Normal Mode

| FREQ (MHz) | S11 (U) | <S11 (DEG) | S21 (U) | <S21 (DEG) | S12 (U) | <S12 (DEG) | S22 (U) | <S22 (DEG) |
|------------|----------|------------|----------|------------|----------|------------|----------|------------|
| 100 | 0.89 | -15.49 | 8.70 | -165.43 | 0.0027 | 108.66 | 0.97 | 51.38 |
| 150 | 0.87 | -22.76 | 8.71 | -179.74 | 0.0038 | 93.41 | 0.96 | 31.54 |
| 200 | 0.85 | -29.87 | 8.53 | 170.16 | 0.0049 | 92.10 | 0.96 | 19.54 |
| 250 | 0.82 | -37.01 | 8.33 | 161.71 | 0.0065 | 86.08 | 0.95 | 11.08 |
| 300 | 0.79 | -43.99 | 8.12 | 154.61 | 0.0071 | 82.95 | 0.94 | 4.19 |
| 350 | 0.75 | -50.47 | 7.75 | 148.41 | 0.0078 | 69.24 | 0.93 | -1.56 |
| 400 | 0.73 | -56.72 | 7.49 | 144.24 | 0.0072 | 71.73 | 0.91 | -5.69 |
| 450 | 0.70 | -63.14 | 7.24 | 139.14 | 0.0078 | 76.99 | 0.91 | -10.06 |
| 500 | 0.67 | -69.13 | 6.97 | 134.34 | 0.0071 | 82.72 | 0.90 | -13.94 |
| 550 | 0.63 | -75.14 | 6.71 | 130.13 | 0.0078 | 84.15 | 0.89 | -17.69 |
| 600 | 0.61 | -81.15 | 6.45 | 126.62 | 0.0074 | 87.69 | 0.88 | -21.14 |
| 650 | 0.59 | -86.84 | 6.23 | 122.98 | 0.0079 | 91.07 | 0.88 | -24.77 |
| 700 | 0.57 | -92.30 | 6.03 | 119.16 | 0.0085 | 103.71 | 0.87 | -28.09 |
| 750 | 0.55 | -97.73 | 5.80 | 115.55 | 0.0098 | 103.73 | 0.87 | -31.38 |
| 800 | 0.54 | -102.99 | 5.56 | 111.56 | 0.0107 | 113.57 | 0.86 | -34.82 |
| 850 | 0.53 | -108.21 | 5.24 | 107.93 | 0.0121 | 115.45 | 0.86 | -38.18 |
| 900 | 0.52 | -113.27 | 4.97 | 105.40 | 0.0134 | 124.98 | 0.86 | -41.51 |
| 950 | 0.51 | -118.12 | 4.75 | 104.08 | 0.0155 | 127.67 | 0.86 | -44.72 |
| 1000 | 0.51 | -122.43 | 4.62 | 102.52 | 0.0175 | 128.87 | 0.86 | -47.96 |
| 1050 | 0.51 | -126.73 | 4.52 | 99.54 | 0.0193 | 128.89 | 0.86 | -51.12 |
| 1100 | 0.50 | -130.83 | 4.34 | 96.33 | 0.0217 | 129.85 | 0.86 | -54.20 |
| 1150 | 0.51 | -134.58 | 4.13 | 93.78 | 0.0238 | 128.74 | 0.86 | -57.23 |
| 1200 | 0.51 | -138.20 | 3.94 | 91.13 | 0.0269 | 131.20 | 0.86 | -60.03 |
| 1250 | 0.51 | -141.69 | 3.72 | 88.49 | 0.0297 | 130.22 | 0.87 | -62.72 |
| 1300 | 0.51 | -145.12 | 3.46 | 86.84 | 0.032 | 128.07 | 0.87 | -65.57 |
| 1350 | 0.52 | -148.25 | 3.25 | 86.69 | 0.033 | 127.73 | 0.87 | -68.10 |

Dual-band RF front-end

SA1920

Table 3. Typical S-Parameters of Low Band LNA at $V_{CC} = +3.75V$, LB Strong Signal Mode

| FREQ (MHz) | S11 (U) | <S11 (DEG) | S21 (U) | <S21 (DEG) | S12 (U) | <S12 (DEG) | S22 (U) | <S22 (DEG) |
|------------|----------|------------|----------|------------|----------|------------|----------|------------|
| 100 | 0.94 | -8.77 | 0.05 | 88.15 | 0.049 | 84.08 | 0.96 | 50.15 |
| 150 | 0.92 | -12.15 | 0.07 | 68.32 | 0.069 | 63.51 | 0.95 | 30.01 |
| 200 | 0.90 | -15.01 | 0.08 | 55.23 | 0.082 | 47.79 | 0.93 | 17.79 |
| 250 | 0.88 | -17.75 | 0.09 | 46.14 | 0.090 | 37.04 | 0.92 | 9.22 |
| 300 | 0.87 | -20.37 | 0.09 | 39.25 | 0.094 | 28.09 | 0.91 | 2.68 |
| 350 | 0.85 | -23.15 | 0.10 | 33.96 | 0.099 | 21.40 | 0.90 | -2.68 |
| 400 | 0.85 | -25.85 | 0.10 | 29.86 | 0.100 | 14.70 | 0.89 | -7.56 |
| 450 | 0.84 | -28.73 | 0.10 | 26.35 | 0.102 | 9.32 | 0.88 | -12.06 |
| 500 | 0.83 | -31.65 | 0.10 | 23.06 | 0.103 | 4.37 | 0.88 | -16.23 |
| 550 | 0.82 | -34.56 | 0.10 | 20.07 | 0.103 | -0.41 | 0.87 | -20.35 |
| 600 | 0.81 | -38.02 | 0.10 | 17.87 | 0.103 | -5.17 | 0.86 | -24.23 |
| 650 | 0.80 | -41.41 | 0.10 | 15.28 | 0.104 | -9.07 | 0.85 | -28.29 |
| 700 | 0.80 | -44.70 | 0.10 | 12.27 | 0.104 | -13.29 | 0.85 | -32.11 |
| 750 | 0.79 | -48.40 | 0.10 | 9.05 | 0.103 | -18.00 | 0.84 | -35.85 |
| 800 | 0.78 | -52.30 | 0.10 | 5.24 | 0.103 | -23.07 | 0.83 | -39.74 |
| 850 | 0.78 | -56.58 | 0.10 | 2.20 | 0.102 | -28.68 | 0.83 | -43.59 |
| 900 | 0.77 | -60.63 | 0.09 | -0.26 | 0.099 | -33.94 | 0.82 | -47.19 |
| 950 | 0.77 | -64.88 | 0.09 | -2.21 | 0.094 | -39.65 | 0.82 | -50.95 |
| 1000 | 0.76 | -69.05 | 0.09 | -4.19 | 0.090 | -44.01 | 0.81 | -54.29 |
| 1050 | 0.76 | -73.21 | 0.09 | -7.58 | 0.086 | -47.95 | 0.81 | -57.67 |
| 1100 | 0.76 | -77.26 | 0.09 | -11.56 | 0.084 | -52.34 | 0.81 | -60.86 |
| 1150 | 0.76 | -81.34 | 0.08 | -16.05 | 0.080 | -58.43 | 0.80 | -64.05 |
| 1200 | 0.76 | -85.37 | 0.08 | -19.50 | 0.076 | -62.90 | 0.80 | -66.96 |
| 1250 | 0.76 | -89.33 | 0.07 | -23.71 | 0.074 | -68.35 | 0.80 | -69.89 |
| 1300 | 0.76 | -93.28 | 0.07 | -27.20 | 0.072 | -75.17 | 0.79 | -72.64 |
| 1350 | 0.75 | -97.37 | 0.06 | -31.20 | 0.068 | -82.58 | 0.79 | -75.21 |

Dual-band RF front-end

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Table 4. Typical S-Parameters of Low Band LNA at $V_{CC} = +3.75V$, LB Transmit On (Analog) Mode

| FREQ (MHz) | S11 (U) | <S11 (DEG) | S21 (U) | <S21 (DEG) | S12 (U) | <S12 (DEG) | S22 (U) | <S22 (DEG) |
|------------|----------|------------|----------|------------|----------|------------|----------|------------|
| 100 | 0.80 | -18.49 | 16.98 | -170.30 | 0.003 | 121.40 | 0.95 | 50.55 |
| 150 | 0.76 | -27.25 | 17.07 | 173.61 | 0.004 | 100.49 | 0.94 | 30.44 |
| 200 | 0.72 | -35.34 | 16.62 | 161.95 | 0.005 | 87.01 | 0.93 | 18.29 |
| 250 | 0.67 | -43.14 | 15.82 | 152.47 | 0.005 | 88.74 | 0.92 | 9.80 |
| 300 | 0.62 | -50.04 | 14.89 | 144.65 | 0.007 | 80.87 | 0.91 | 2.68 |
| 350 | 0.57 | -55.41 | 13.73 | 138.33 | 0.007 | 64.95 | 0.89 | -2.99 |
| 400 | 0.55 | -61.58 | 12.97 | 134.43 | 0.007 | 90.16 | 0.87 | -6.38 |
| 450 | 0.51 | -67.13 | 12.27 | 129.49 | 0.007 | 90.97 | 0.86 | -10.66 |
| 500 | 0.47 | -72.08 | 11.53 | 125.20 | 0.008 | 89.19 | 0.85 | -14.35 |
| 550 | 0.44 | -76.94 | 10.83 | 121.58 | 0.009 | 96.23 | 0.84 | -17.92 |
| 600 | 0.42 | -81.92 | 10.24 | 118.69 | 0.009 | 98.83 | 0.84 | -21.27 |
| 650 | 0.40 | -86.62 | 9.78 | 115.74 | 0.009 | 102.03 | 0.83 | -24.85 |
| 700 | 0.38 | -91.05 | 9.32 | 112.66 | 0.010 | 107.95 | 0.83 | -28.04 |
| 750 | 0.37 | -95.76 | 8.89 | 109.66 | 0.012 | 108.58 | 0.83 | -31.27 |
| 800 | 0.36 | -100.37 | 8.46 | 106.44 | 0.012 | 114.73 | 0.82 | -34.68 |
| 850 | 0.35 | -105.06 | 7.92 | 103.48 | 0.014 | 115.62 | 0.82 | -38.05 |
| 900 | 0.34 | -109.12 | 7.39 | 101.58 | 0.015 | 116.40 | 0.82 | -41.29 |
| 950 | 0.34 | -113.76 | 7.02 | 100.76 | 0.017 | 116.04 | 0.82 | -44.70 |
| 1000 | 0.34 | -117.50 | 6.81 | 99.95 | 0.019 | 122.13 | 0.82 | -47.58 |
| 1050 | 0.34 | -121.31 | 6.64 | 97.57 | 0.021 | 122.61 | 0.83 | -50.73 |
| 1100 | 0.34 | -124.67 | 6.36 | 94.92 | 0.023 | 121.36 | 0.83 | -53.76 |
| 1150 | 0.35 | -127.76 | 6.09 | 92.79 | 0.025 | 123.58 | 0.83 | -56.81 |
| 1200 | 0.35 | -130.93 | 5.80 | 90.59 | 0.026 | 125.25 | 0.83 | -59.62 |
| 1250 | 0.36 | -133.78 | 5.48 | 88.25 | 0.030 | 123.53 | 0.84 | -62.32 |
| 1300 | 0.36 | -136.90998 | 5.10 | 87.00 | 0.03 | 122.37 | 0.84 | -65.27 |
| 1350 | 0.37 | -140.02216 | 4.82 | 87.05 | 0.03 | 122.64 | 0.85 | -68.06 |

Dual-band RF front-end

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Table 5. Typical S-Parameters of Low Band Mixer Input at $V_{CC} = +3.75V$, LB Receive Normal Mode

| FREQ (MHz) | S11 (U) | <S11 (DEG) |
|------------|----------|------------|
| 100 | 0.85 | -13.10 |
| 150 | 0.84 | -17.65 |
| 200 | 0.85 | -23.74 |
| 250 | 0.85 | -29.63 |
| 300 | 0.85 | -37.49 |
| 350 | 0.85 | -45.23 |
| 400 | 0.85 | -54.50 |
| 450 | 0.80 | -64.14 |
| 500 | 0.75 | -73.90 |
| 550 | 0.70 | -82.34 |
| 600 | 0.67 | -91.47 |
| 650 | 0.57 | -100.54 |
| 700 | 0.53 | -106.44 |
| 750 | 0.51 | -114.37 |
| 800 | 0.49 | -123.87 |
| 850 | 0.48 | -132.17 |
| 900 | 0.49 | -141.42 |
| 950 | 0.47 | -150.07 |
| 1000 | 0.47 | -160.64 |
| 1050 | 0.47 | -169.49 |
| 1100 | 0.47 | -179.79 |
| 1150 | 0.48 | 171.14 |
| 1200 | 0.48 | 162.01 |
| 1250 | 0.49 | 154.08 |
| 1300 | 0.50 | 144.55 |
| 1350 | 0.51 | 136.11 |

Dual-band RF front-end

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Table 6. Typical S-Parameters of Low Band LO Input at $V_{CC} = +3.75V$, LB Receive Normal Mode

| FREQ (MHz) | S11 (U) | <S11 (DEG) |
|------------|----------|------------|
| 100 | 0.76 | -55.83 |
| 150 | 0.73 | -78.35 |
| 200 | 0.70 | -98.64 |
| 250 | 0.68 | -116.73 |
| 300 | 0.66 | -133.17 |
| 350 | 0.64 | -147.82 |
| 400 | 0.61 | -161.51 |
| 450 | 0.59 | -173.68 |
| 500 | 0.55 | 173.99 |
| 550 | 0.51 | 162.15 |
| 600 | 0.46 | 150.30 |
| 650 | 0.38 | 140.69 |
| 700 | 0.29 | 132.76 |
| 750 | 0.18 | 131.71 |
| 800 | 0.10 | 171.44 |
| 850 | 0.18 | -150.19 |
| 900 | 0.31 | -149.41 |
| 950 | 0.42 | -157.78 |
| 1000 | 0.50 | -166.73 |
| 1050 | 0.57 | -175.14 |
| 1100 | 0.61 | 177.49 |
| 1150 | 0.64 | 170.74 |
| 1200 | 0.66 | 164.22 |
| 1250 | 0.68 | 157.61 |
| 1300 | 0.68 | 150.89 |
| 1350 | 0.65 | 144.80 |

Dual-band RF front-end

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Table 7. Typical S-Parameters of HB LNA Input at $V_{CC} = +3.75V$, HB Receive Normal Mode

| FREQ (MHz) | S11 (U) | <S11 (DEG) |
|------------|----------|------------|
| 1400 | 0.58 | -135.43 |
| 1450 | 0.59 | -138.48 |
| 1500 | 0.59 | -141.42 |
| 1550 | 0.60 | -144.44 |
| 1600 | 0.62 | -146.93 |
| 1650 | 0.63 | -149.85 |
| 1700 | 0.65 | -154.08 |
| 1750 | 0.66 | -158.38 |
| 1800 | 0.66 | -162.67 |
| 1850 | 0.66 | -167.09 |
| 1900 | 0.65 | -170.72 |
| 1950 | 0.63 | -172.76 |
| 2000 | 0.64 | -175.38 |
| 2050 | 0.61 | -178.44 |
| 2100 | 0.60 | -179.38 |
| 2150 | 0.59 | 179.32 |
| 2200 | 0.58 | 178.44 |
| 2250 | 0.58 | 177.61 |
| 2300 | 0.57 | 176.29 |
| 2350 | 0.57 | 175.39 |
| 2400 | 0.57 | 174.35 |
| 2450 | 0.56 | 173.01 |
| 2500 | 0.57 | 172.12 |
| 2550 | 0.57 | 170.91 |
| 2600 | 0.56 | 169.89 |
| 2650 | 0.56 | 168.41 |

Dual-band RF front-end

SA1920

Table 8. Typical S-Parameters of HB LNA Input at $V_{CC} = +3.75V$, HB Strong Signal Mode

| FREQ (MHz) | S11 (U) | <S11 (DEG) |
|------------|----------|------------|
| 1400 | 0.81 | -73.99 |
| 1450 | 0.81 | -77.23 |
| 1500 | 0.81 | -80.62 |
| 1550 | 0.80 | -84.00 |
| 1600 | 0.80 | -87.02 |
| 1650 | 0.80 | -90.35 |
| 1700 | 0.79 | -93.54 |
| 1750 | 0.79 | -96.48 |
| 1800 | 0.79 | -100.32 |
| 1850 | 0.79 | -103.54 |
| 1900 | 0.79 | -107.23 |
| 1950 | 0.79 | -110.05 |
| 2000 | 0.77 | -113.75 |
| 2050 | 0.78 | -114.79 |
| 2100 | 0.79 | -117.61 |
| 2150 | 0.79 | -120.50 |
| 2200 | 0.80 | -122.65 |
| 2250 | 0.79 | -125.91 |
| 2300 | 0.80 | -128.17 |
| 2350 | 0.79 | -130.64 |
| 2400 | 0.79 | -133.19 |
| 2450 | 0.79 | -135.66 |
| 2500 | 0.79 | -138.22 |
| 2550 | 0.79 | -140.56 |
| 2600 | 0.79 | -143.22 |
| 2650 | 0.79 | -145.47 |

Dual-band RF front-end

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Table 9. Typical S-Parameters of HB LO Input at $V_{CC} = +3.75V$, HB Receive Normal Mode

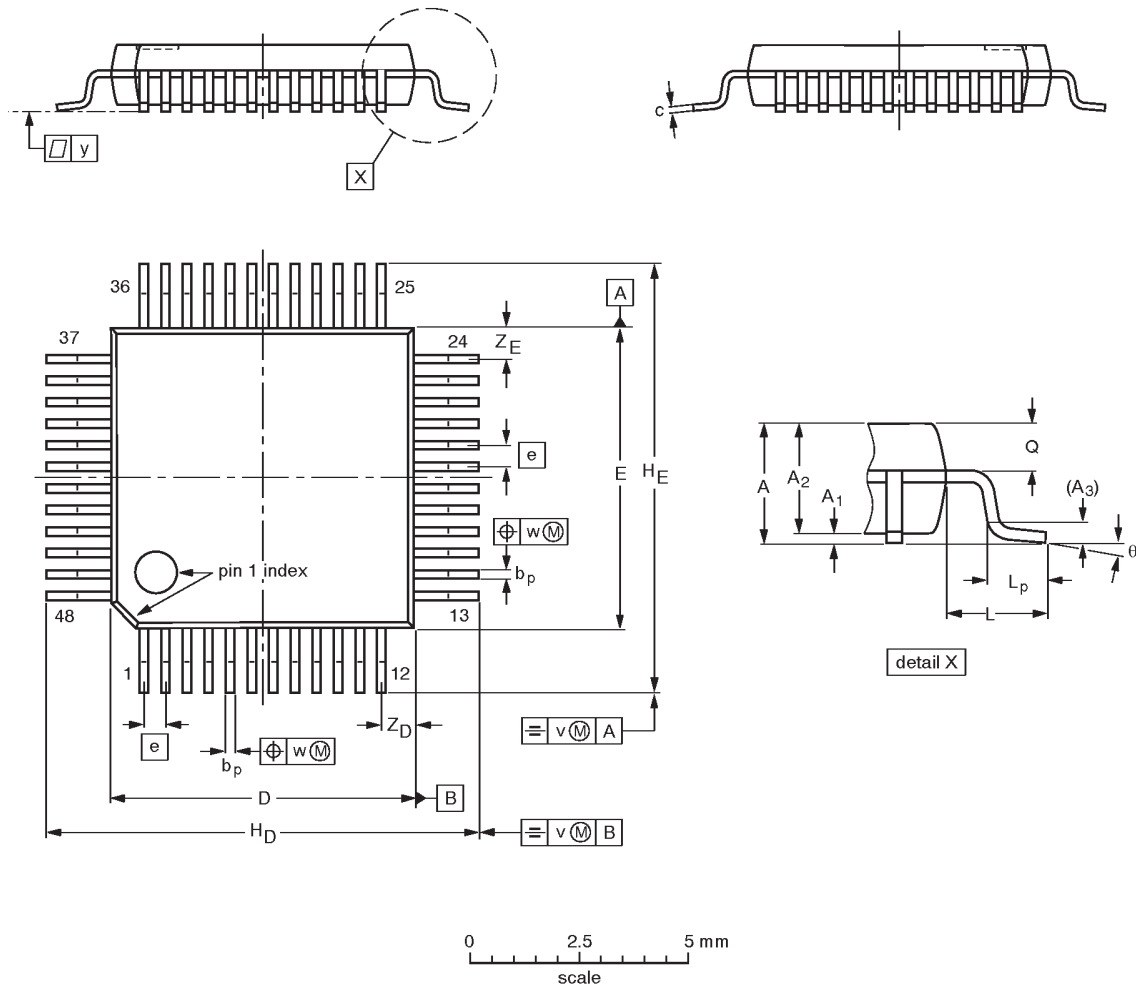
| FREQ (MHz) | S11 (U) | <S11 (DEG) |
|------------|----------|------------|
| 1400 | 0.62 | -87.50 |
| 1450 | 0.61 | -90.87 |
| 1500 | 0.60 | -94.44 |
| 1550 | 0.60 | -98.86 |
| 1600 | 0.59 | -102.10 |
| 1650 | 0.59 | -106.34 |
| 1700 | 0.58 | -110.67 |
| 1750 | 0.57 | -114.48 |
| 1800 | 0.57 | -119.86 |
| 1850 | 0.55 | -126.14 |
| 1900 | 0.48 | -134.66 |
| 1950 | 0.43 | -123.95 |
| 2000 | 0.47 | -126.26 |
| 2050 | 0.48 | -128.33 |
| 2100 | 0.50 | -131.34 |
| 2150 | 0.50 | -135.52 |
| 2200 | 0.50 | -138.76 |
| 2250 | 0.50 | -142.68 |
| 2300 | 0.50 | -146.60 |
| 2350 | 0.49 | -150.21 |
| 2400 | 0.49 | -154.30 |
| 2450 | 0.48 | -157.62 |
| 2500 | 0.47 | -161.79 |
| 2550 | 0.46 | -166.32 |
| 2600 | 0.45 | -170.41 |
| 2650 | 0.43 | -174.86 |

Dual-band RF front-end

SA1920

LQFP48: plastic low profile quad flat package; 48 leads; body 7 x 7 x 1.4 mm

SOT313-2



DIMENSIONS (mm are the original dimensions)

| UNIT | A max. | A ₁ | A ₂ | A ₃ | b _p | c | D ⁽¹⁾ | E ⁽¹⁾ | e | H _D | H _E | L | L _p | Q | v | w | y | Z _D ⁽¹⁾ | Z _E ⁽¹⁾ | θ |
|------|--------|----------------|----------------|----------------|----------------|--------------|------------------|------------------|-----|----------------|----------------|-----|----------------|--------------|-----|------|-----|-------------------------------|-------------------------------|----------|
| mm | 1.60 | 0.20 0.05 | 1.45 1.35 | 0.25 | 0.27 0.17 | 0.18 0.12 | 7.1 6.9 | 7.1 6.9 | 0.5 | 9.15 8.85 | 9.15 8.85 | 1.0 | 0.75 0.45 | 0.69 0.59 | 0.2 | 0.12 | 0.1 | 0.95 0.55 | 0.95 0.55 | 7° 0° |

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|-------|------|--|---------------------|----------------------|
| | IEC | JEDEC | EIAJ | | | |
| SOT313-2 | | | | | | 93-06-15 94-12-19 |

Dual-band RF front-end

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NOTES

Dual-band RF front-end

SA1920

Data sheet status

| Data sheet status | Product status | Definition [1] |
|---------------------------|----------------|--|
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